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Novel Terahertz Metamaterials

A.J. Taylor

University of Rochester, Institute of Optics Colloquium

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Collaborators/Acknowledgements

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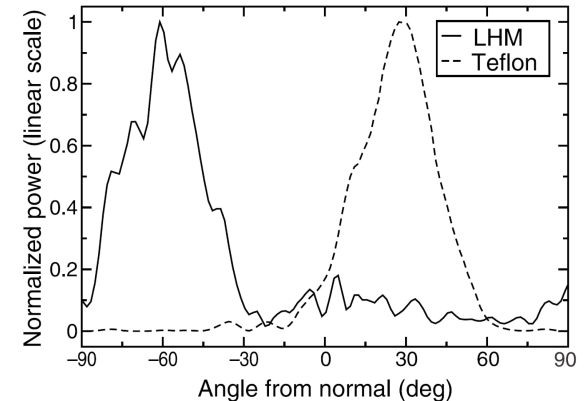
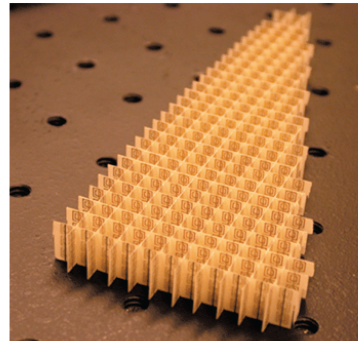
Outline

- **Metamaterials as a solution to the Terahertz (THz) Gap**
- **THz functionalities achieved in few-layered ultrathin planar metamaterials**
 - Antireflection
 - Perfect absorption
 - Linear polarization conversion
 - Anomalous reflection/refraction (generalized Snell's law)
- **Active THz Metamaterials**
 - modulator/switch
 - active frequency tuning
 - spatial modulator
 - thermal and optical tuning using complex oxides
- **Summary**

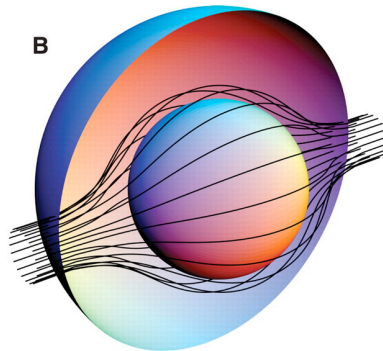
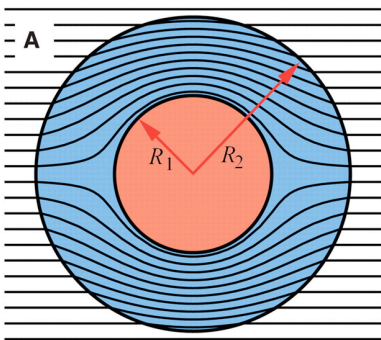


Emergent Phenomena in Metamaterials

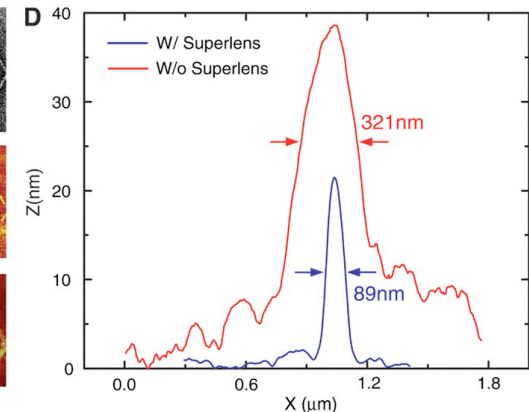
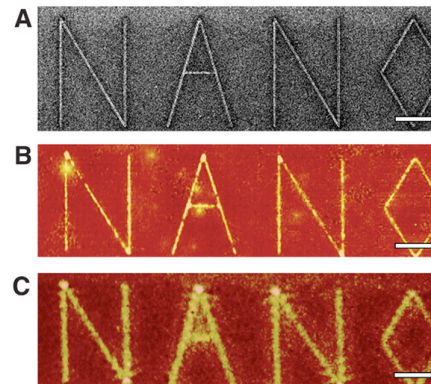
- Metamaterials are a class of man-made effective media with properties attained from their subwavelength structures rather than the chemical compositions



- Negative index of refraction



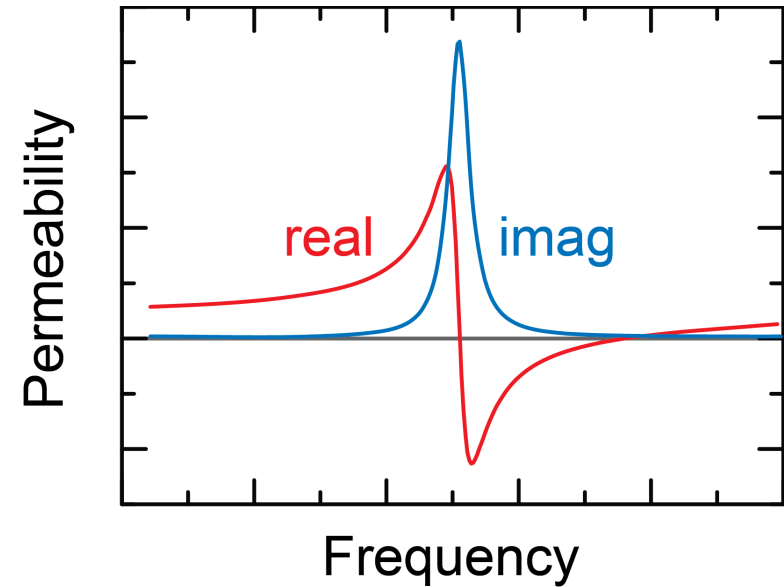
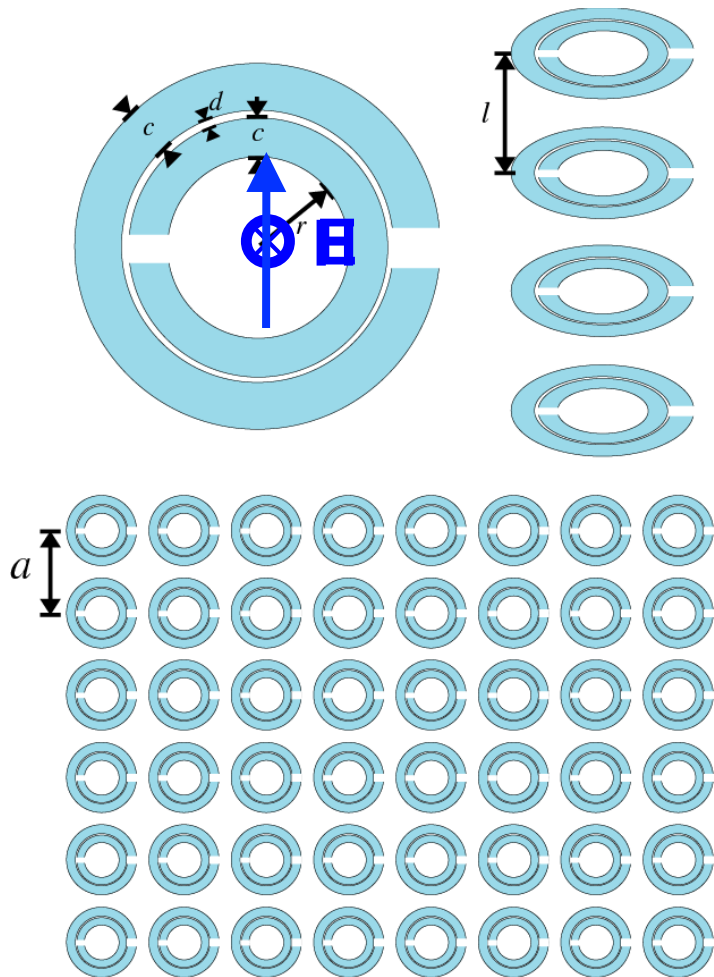
- Cloaking and transformation optics



- Superlens – breaking the diffraction limits



Tunable μ and ϵ : the Split Ring Resonator (SRR)



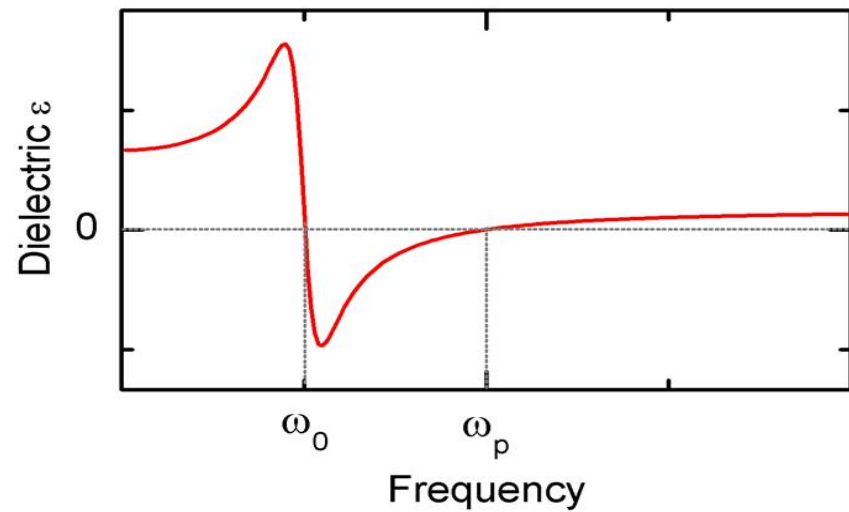
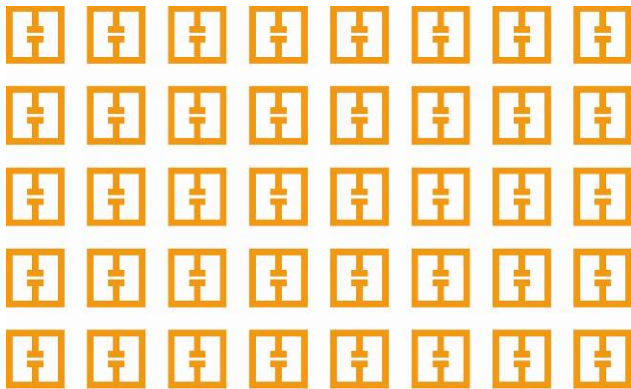
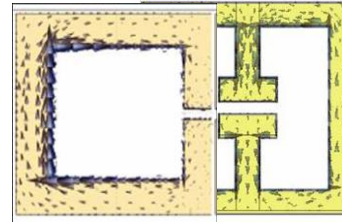
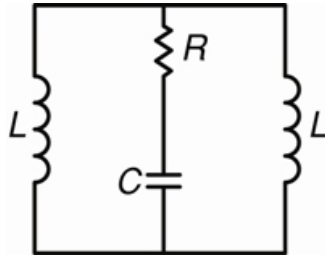
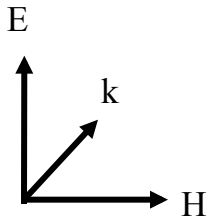
➤ Magnetic resonance

➤ Electric resonance

$$\mu_{eff} = 1 - \frac{\frac{\pi r^2}{a^2}}{1 + \frac{2\sigma i}{\omega r \mu_0} - \frac{3}{\pi^2 \mu_0 \omega^2 C r^3}}$$



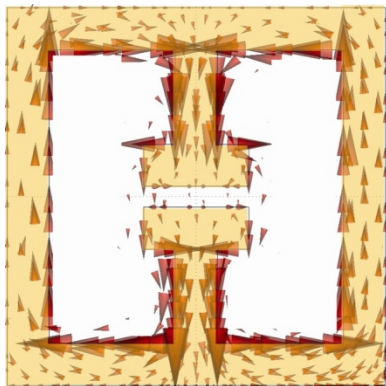
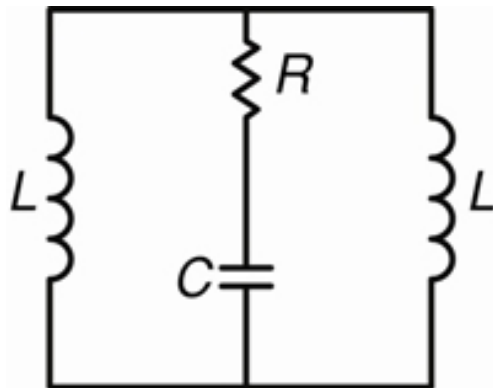
Tunable Electric Metamaterials



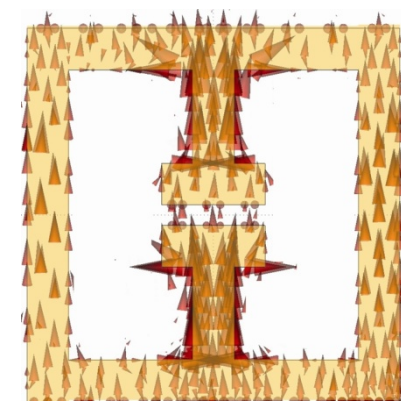
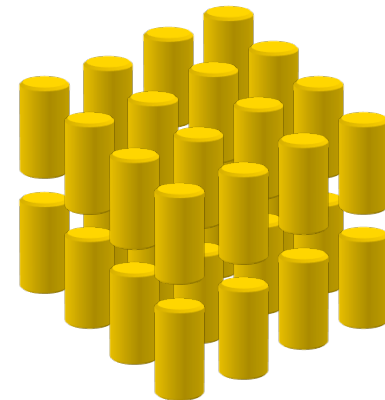
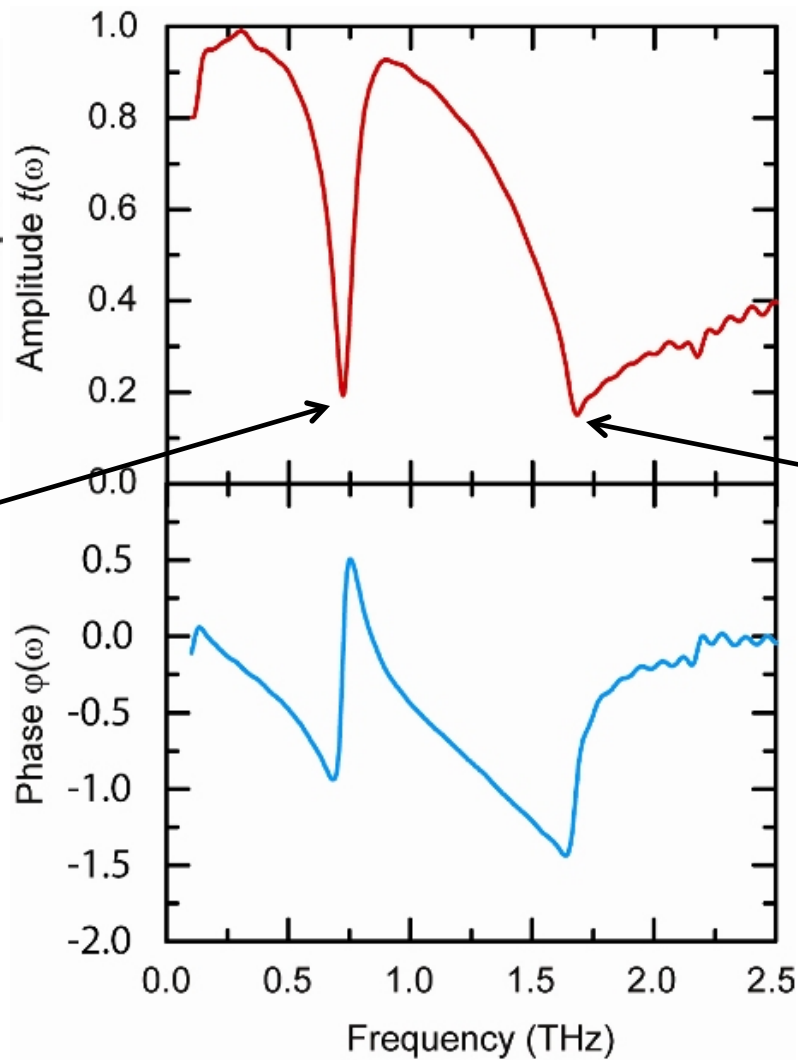
$$\epsilon < 0 \text{ when } \omega_0 < \omega < \omega_p$$



Metamaterial Electric Resonances



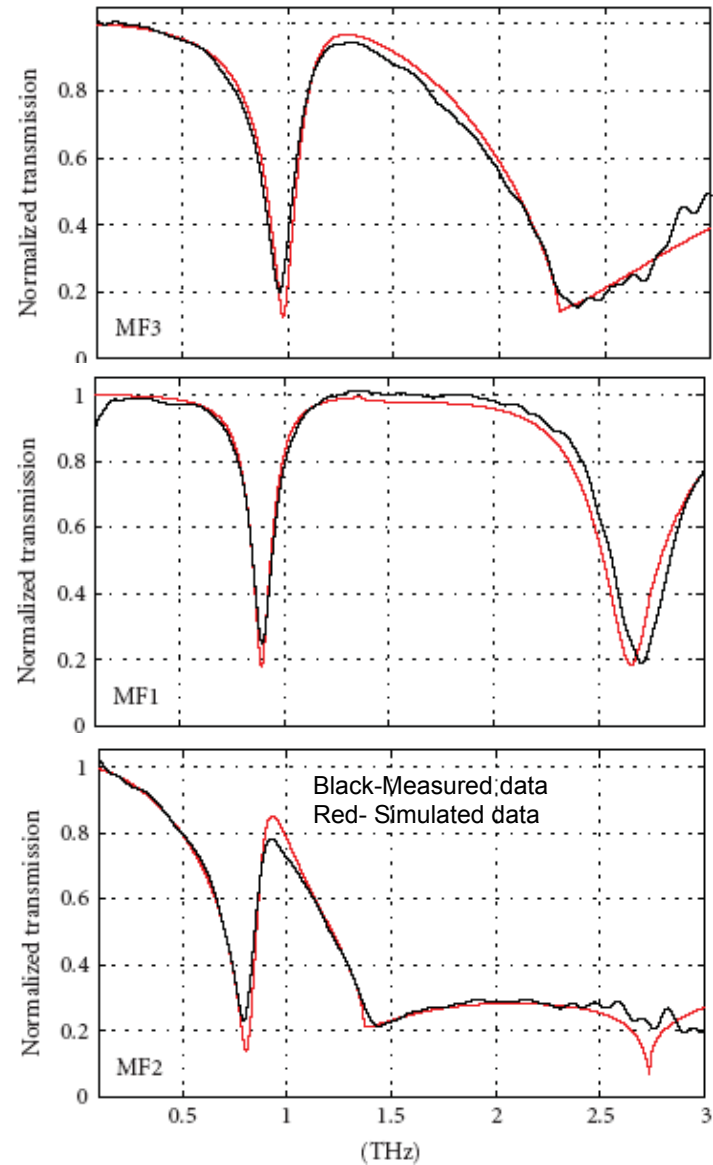
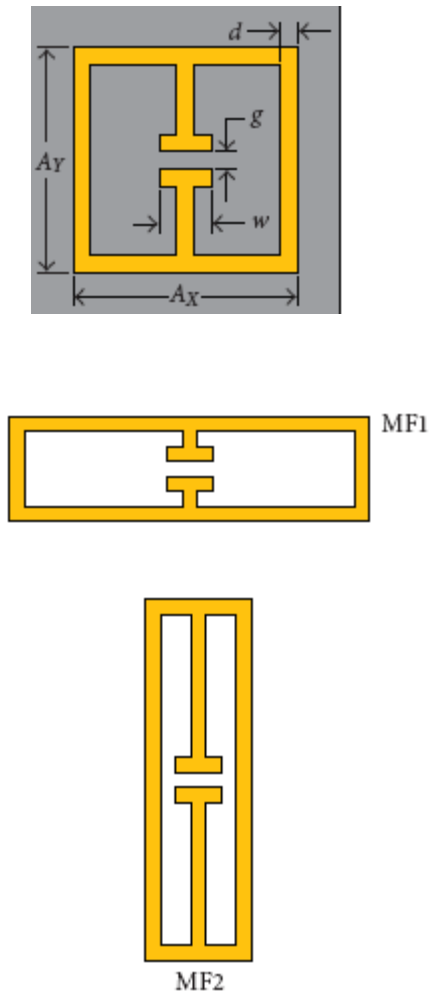
RLC resonance



Collective dipolar resonance



Rectangular eSRR – Engineering Resonances

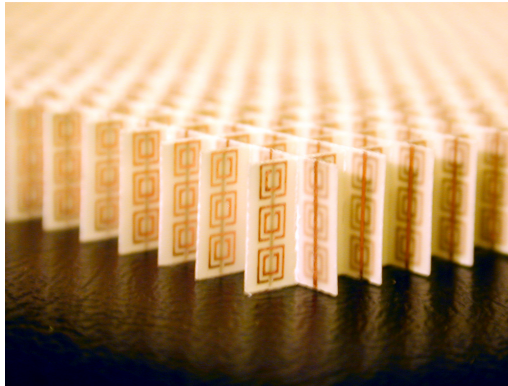
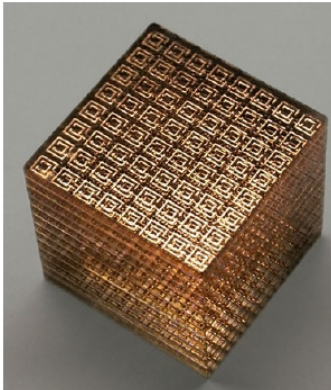




Bulk Metamaterials vs Planar Meta-Surfaces

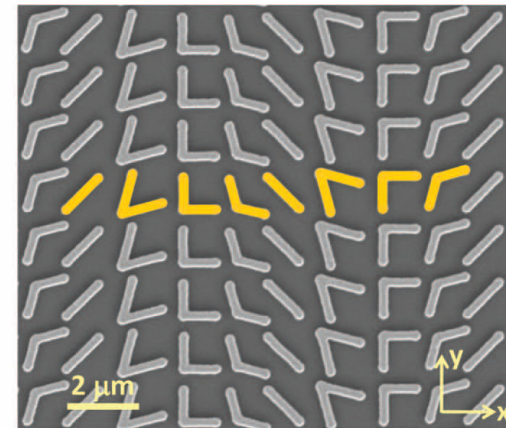
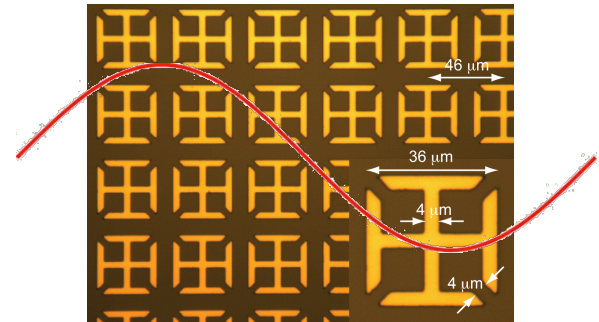
Bulk metamaterials

- ❑ Effective material parameters: ϵ , μ , Z , n
- ❑ Feasible mostly at microwave frequencies
- ❑ Difficult to fabricate in the optical regime



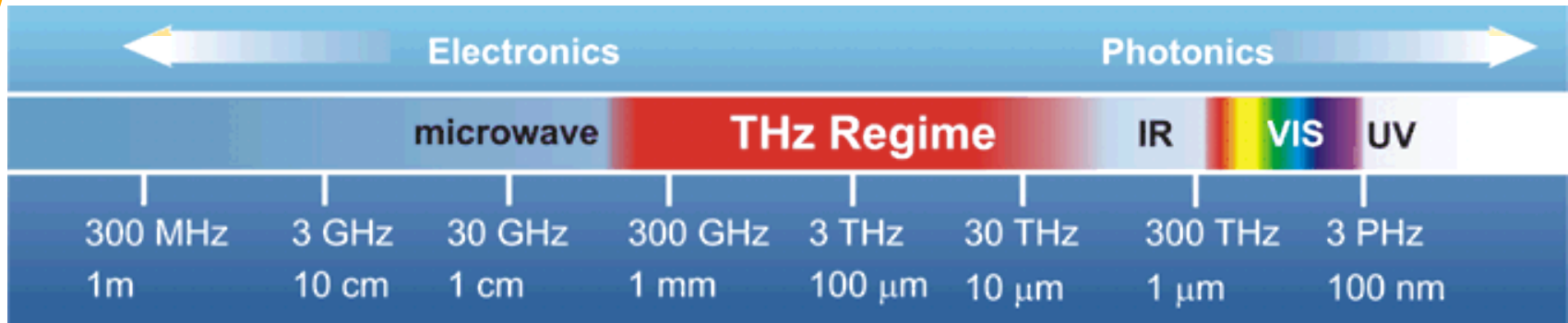
Meta-surfaces

- ❑ Effective surface properties
- ❑ Any relevant frequency
- ❑ Planar structures: ease in fabrication

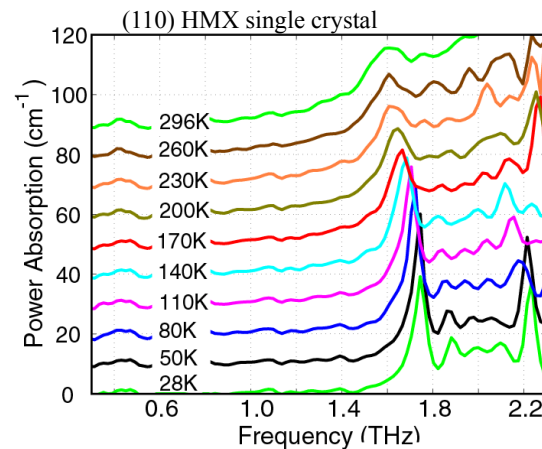




Terahertz Gap

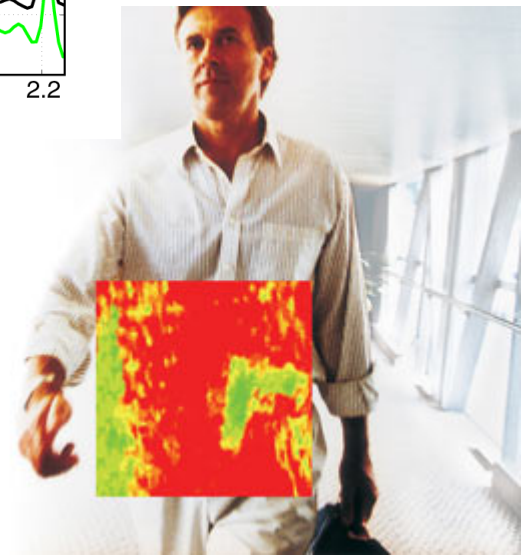


- THz region is located at the interface of electronics and photonics where technologies directly translated from microwave and optical regimes generally fail to operate.
- THz gap is caused by weak materials response at THz frequencies
- Results in a lack of sources, detectors, modulators, filters, polarizers, sensors, etc. in the THz regime.



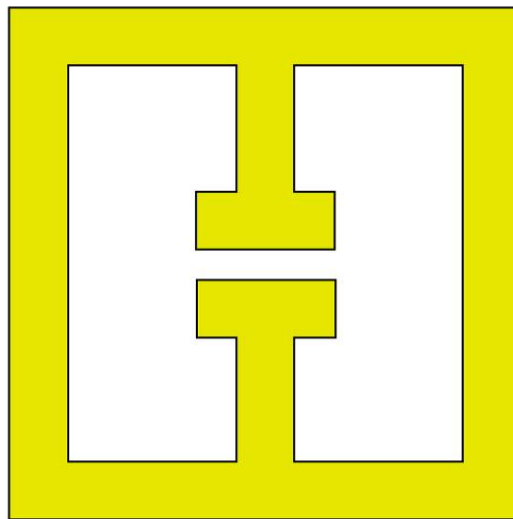
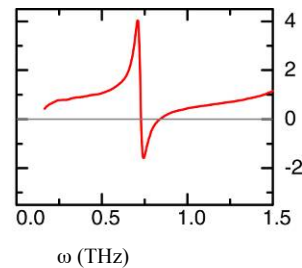
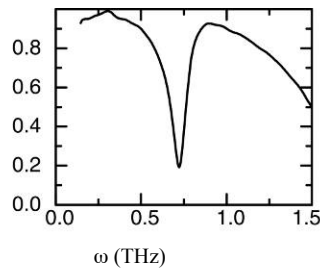
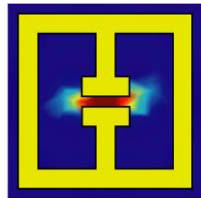
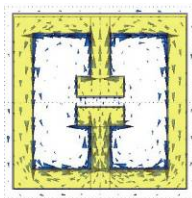
Spectroscopy

Imaging





Metamaterials: A solution to the THz Gap



Typical parameters:

Unit cell: 50 μm

Outer dimension: 36 μm

Line width: 4 μm

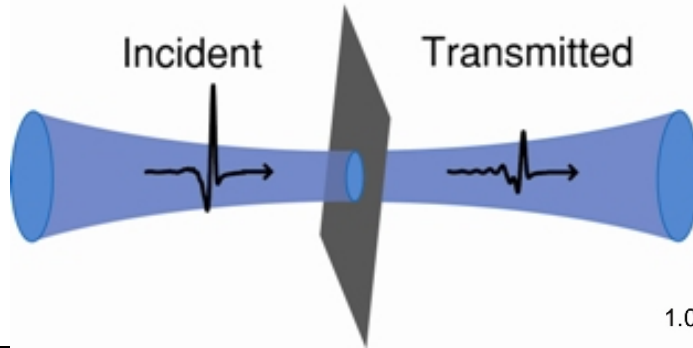
Split gap: 2 μm

Resonance enhances THz interactions

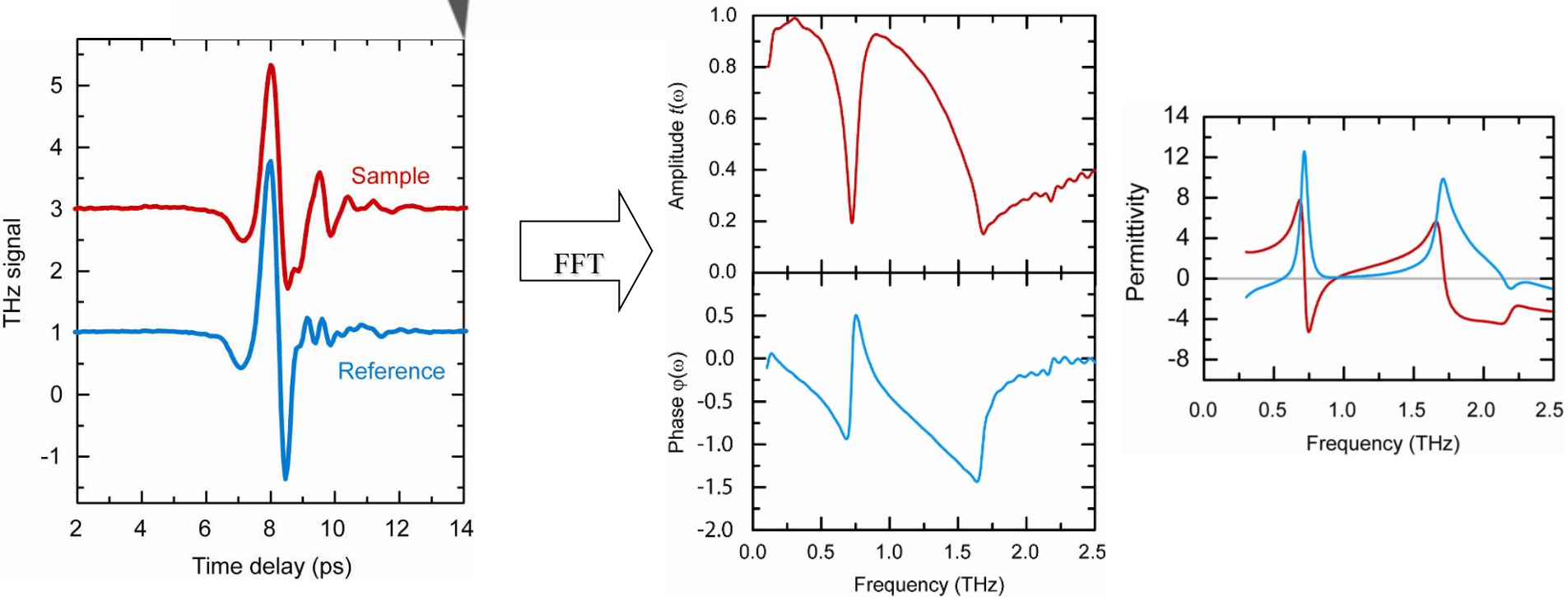
- Modulators (AM, FM, PM)
- Filters
- Sensors



Terahertz Time Domain Spectroscopy (THz-TDS)

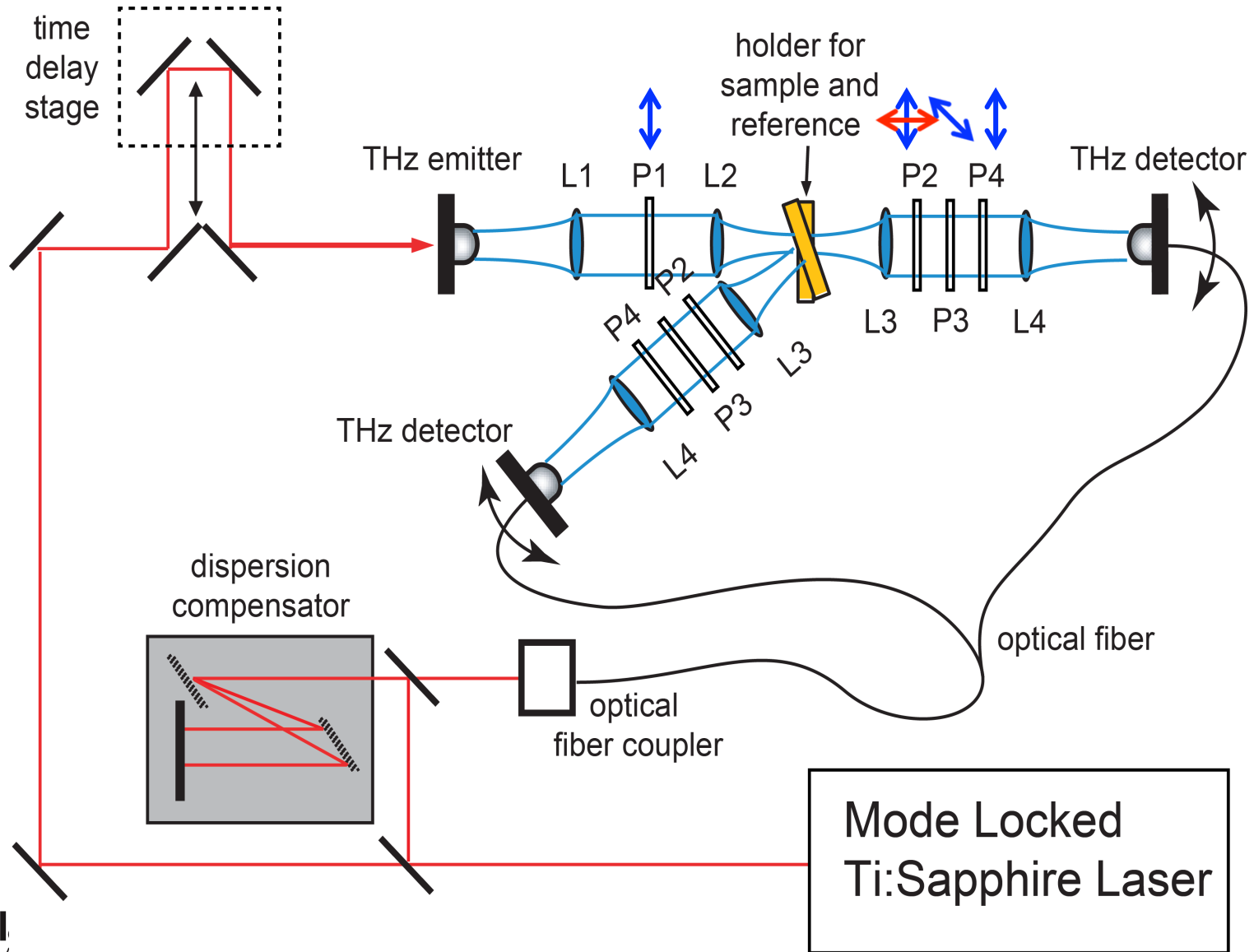


$$\tilde{t}(\omega) = \frac{E_{\text{Sam}}(\omega)}{E_{\text{Ref}}(\omega)}$$



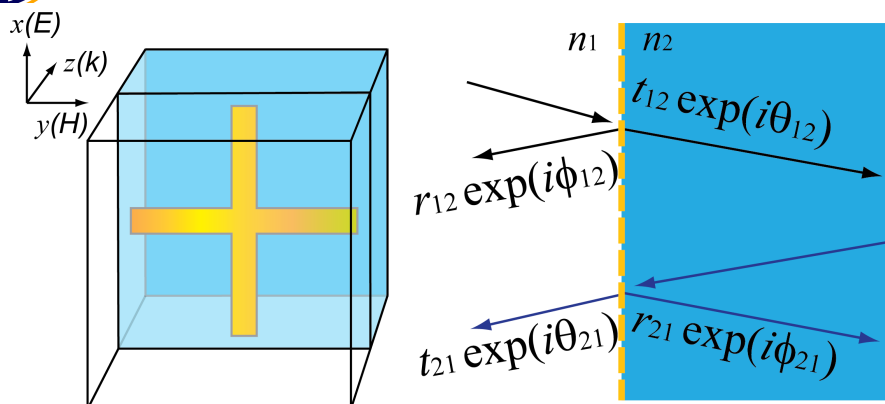


THz spectroscopy in reflection: angular dependence





Tailored Transmission and Reflection



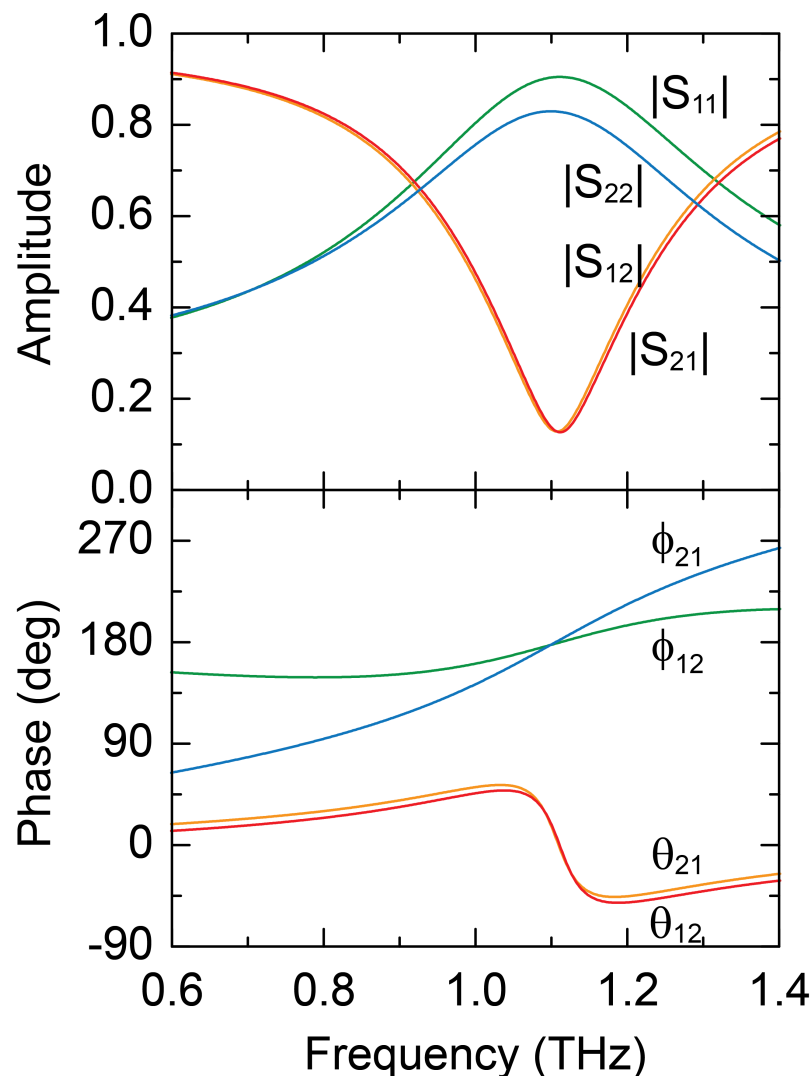
- ❑ The resonator array modifies the complex reflection and transmission coefficients at the interface

$$r_{12} = |S_{11}| \quad t_{12} = \sqrt{\frac{n_1}{n_2}} |S_{21}|$$

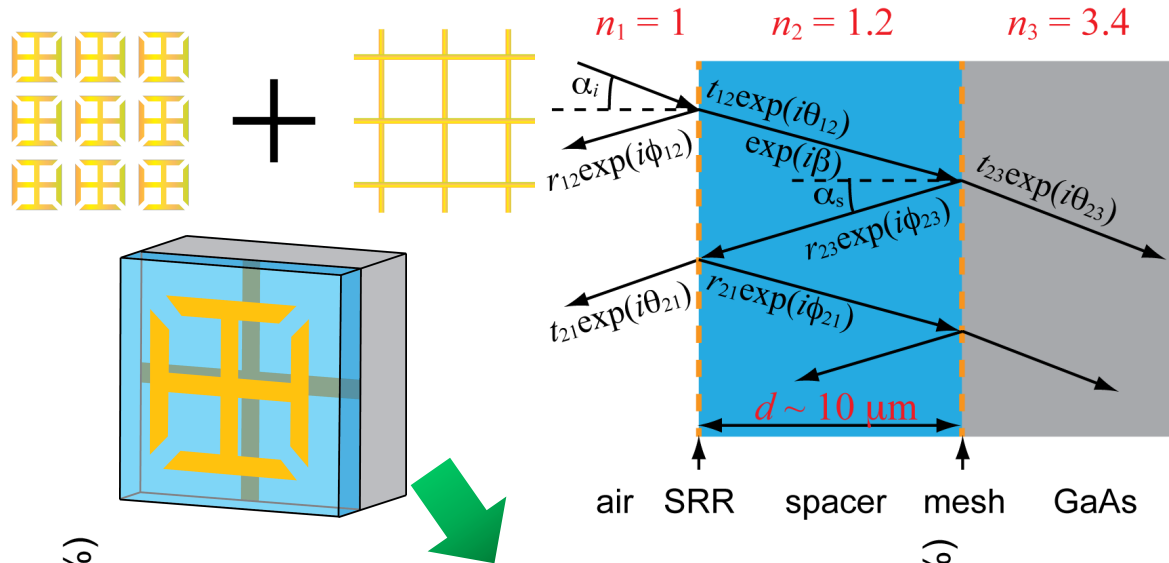
$$r_{21} = |S_{22}| \quad t_{21} = \sqrt{\frac{n_2}{n_1}} |S_{21}|$$

$$\phi_{12} = \arctan(S_{11}) \quad \theta_{12} = \arctan(S_{21})$$

$$\phi_{21} = \arctan(S_{22}) \quad \theta_{12} = \arctan(S_{12})$$

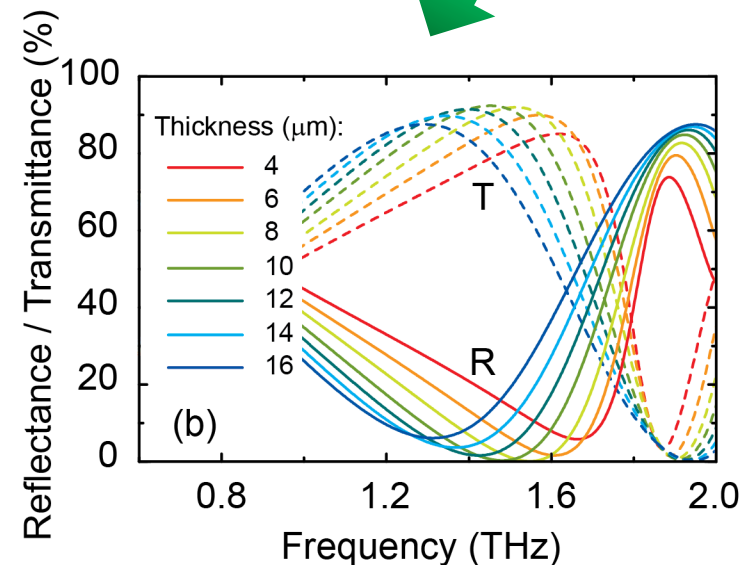
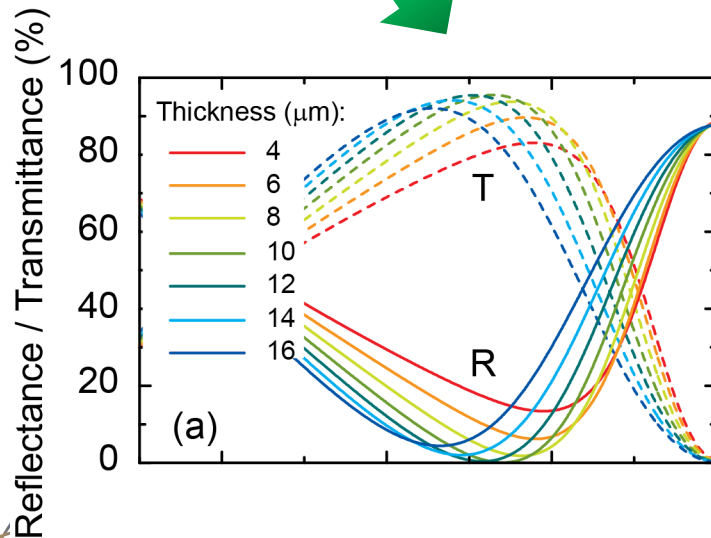


Ultrathin Metamaterial Anti-Reflection Coating



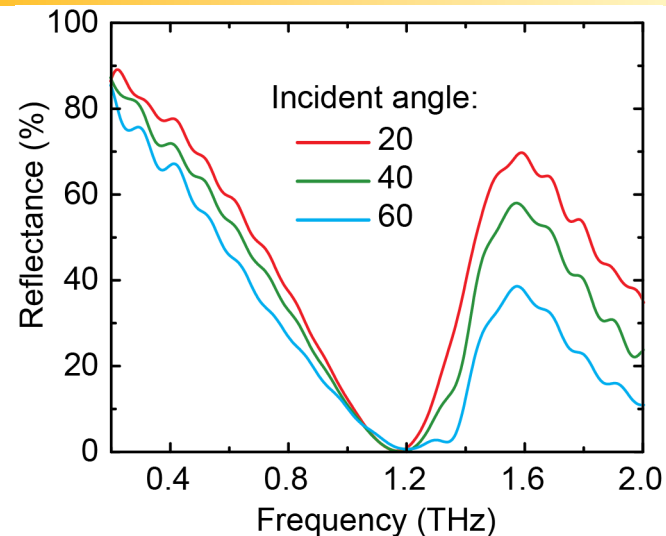
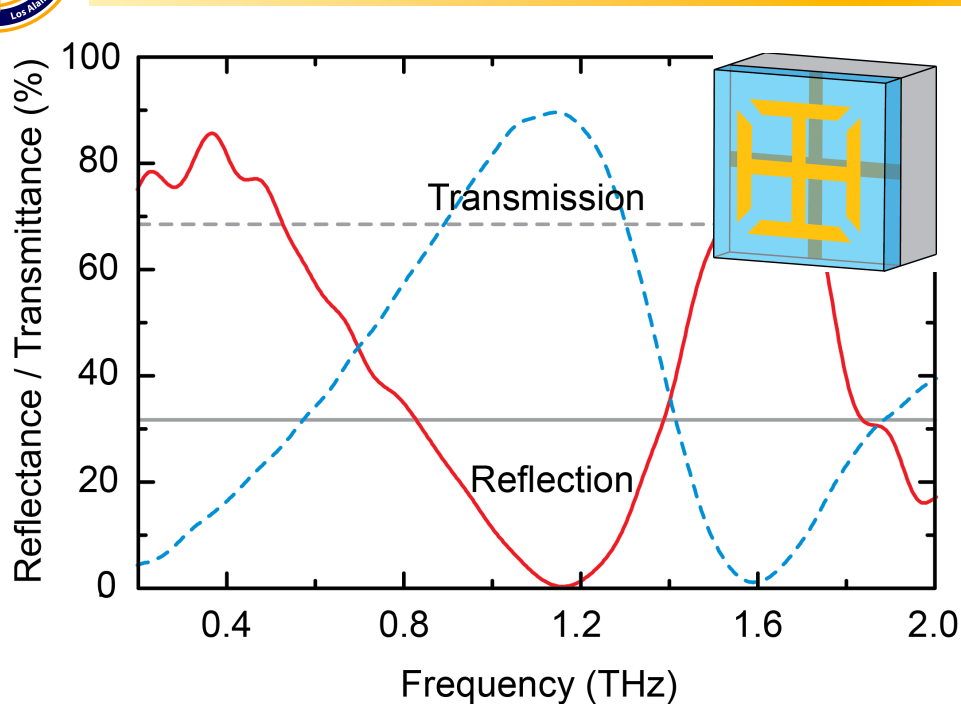
$$\tilde{r} = \tilde{r}_{12} + \frac{\tilde{t}_{12}\tilde{t}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}{1 - \tilde{r}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}$$

$$\tilde{t} = \frac{\tilde{t}_{12}\tilde{t}_{23}e^{i\tilde{\beta}}}{1 - \tilde{r}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}$$

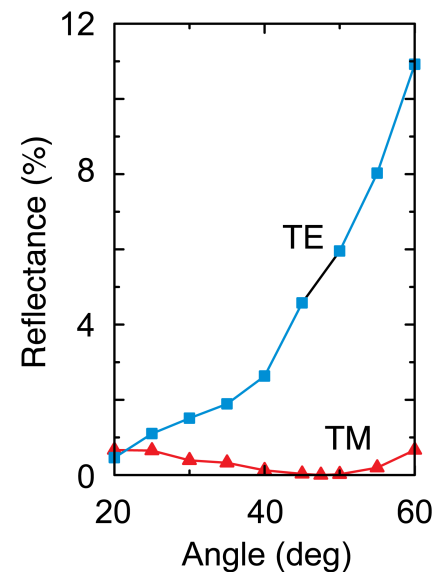




Ultrathin Metamaterial ARC: Experiments

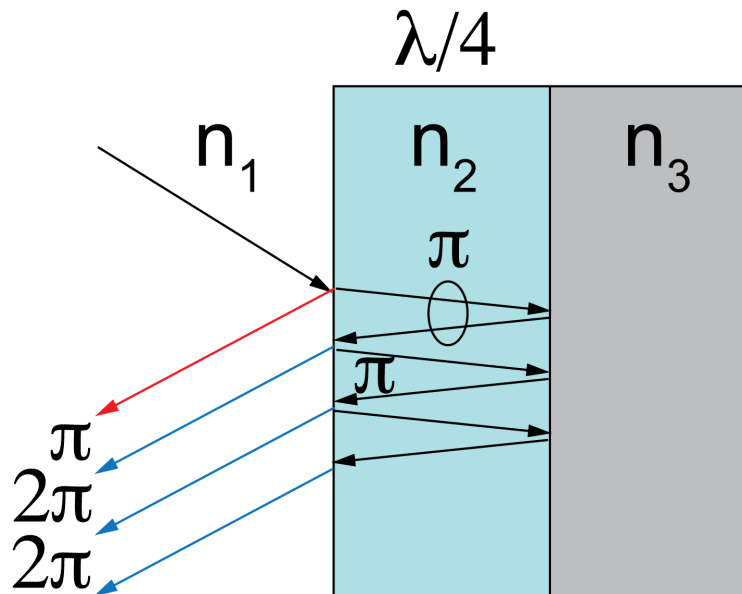


- ❑ Reflectance: 32% \rightarrow ~0
- ❑ Transmittance: 68% \rightarrow 90%
- ❑ Transmittance does not reach 100% due to losses
- ❑ Operate over a wide incident angle range
- ❑ Brewster angle behavior for TM polarization

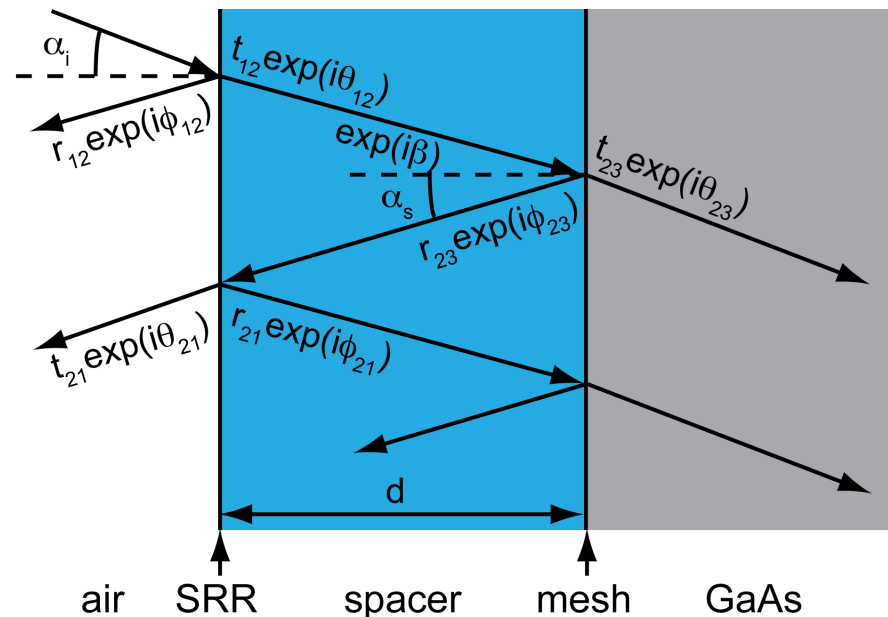




Comparison to Quarter-Wave Antireflection



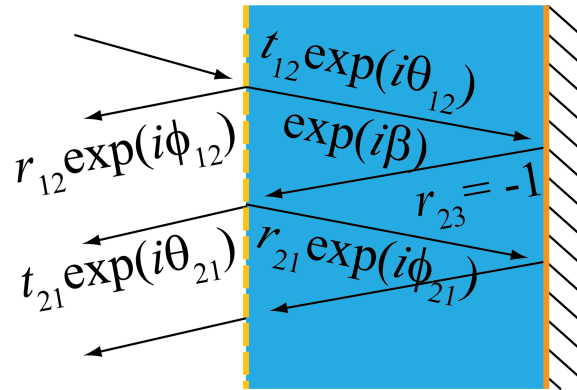
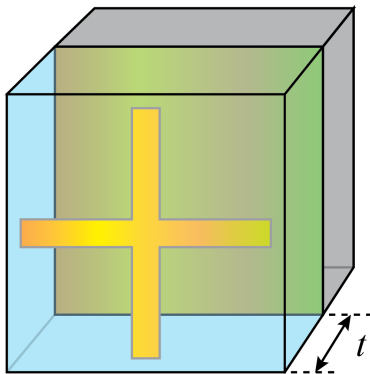
- $n_2 = (n_1 n_3)^{1/2} \setminus r_{12} = r_{21} = r_{23}$
- Phase difference π between direct reflection and second reflection
- Phase difference 2π in the following reflections



- At antireflection frequency $r_{12} = r_{21} = r_{23}$
- $(\theta_{12} + \phi_{23} + \theta_{21} + 2\beta) - \phi_{12} = \pi$ between direct reflection and second reflection
- $\phi_{21} + \phi_{23} + 2\beta = 0 (2\pi)$ in the following reflections

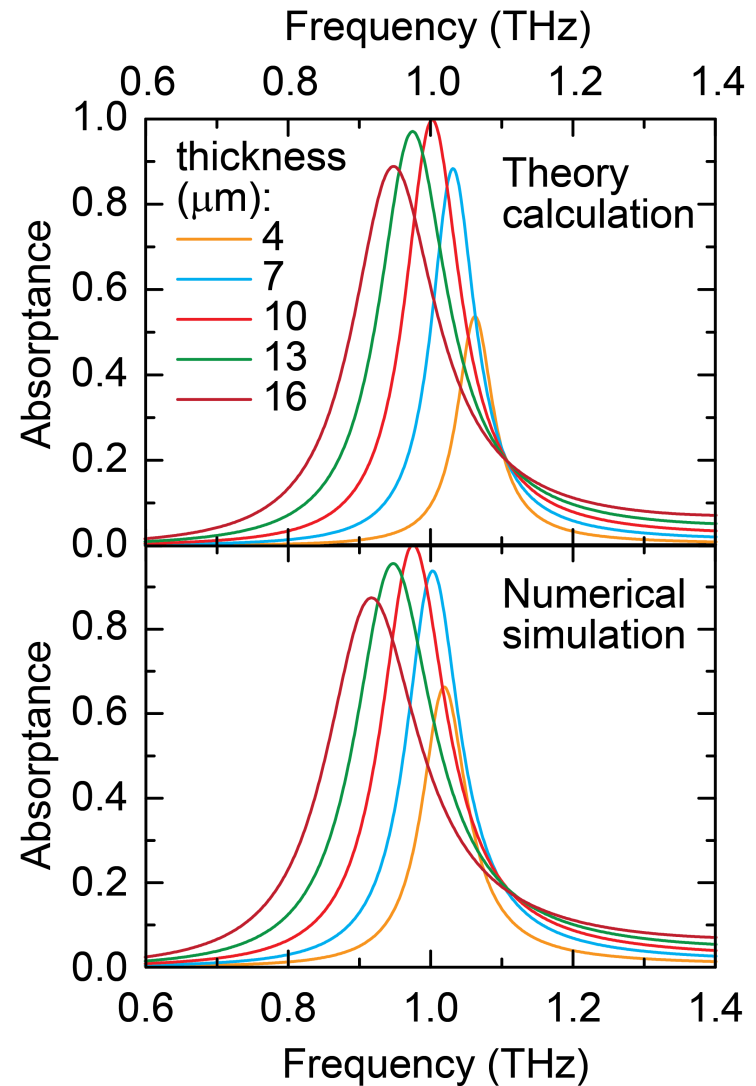


Metamaterial Perfect Absorbers: Trapped Light



$$\tilde{r} = \tilde{r}_{12} + \frac{\tilde{t}_{12}\tilde{t}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}{1 - \tilde{r}_{21}\tilde{r}_{23}e^{i2\tilde{\beta}}}$$

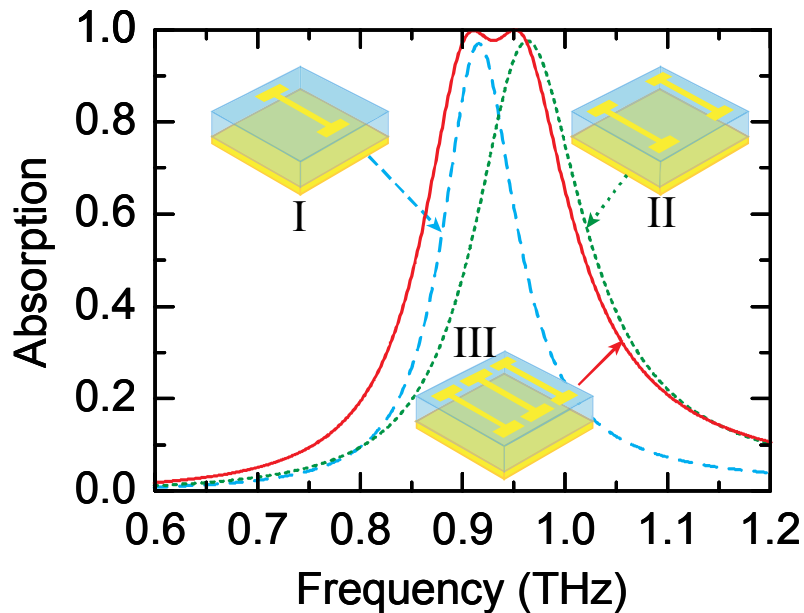
- ❑ Zero transmission due to the metal ground plane
- ❑ Minimizing reflection due to destructive interference of multi-reflection



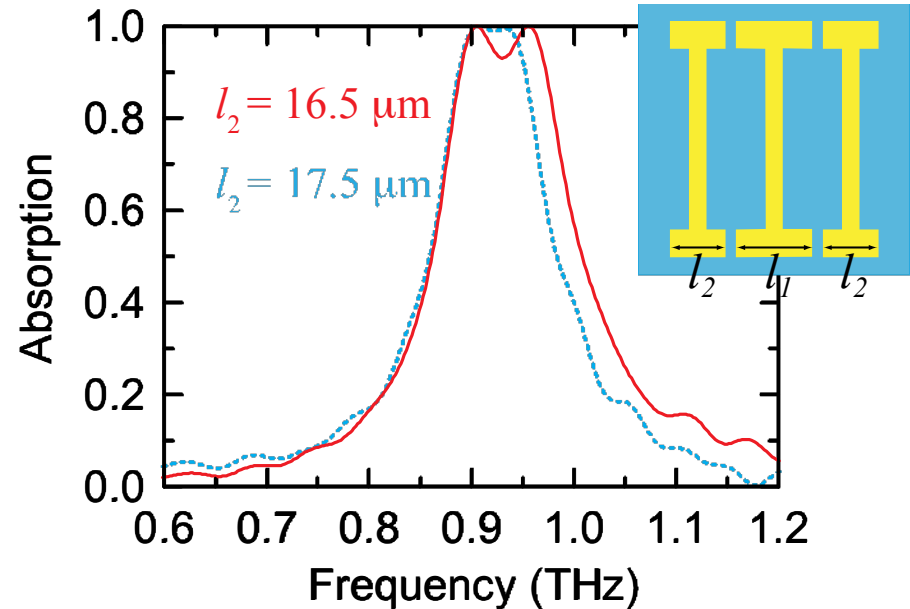


Bandwidth Broadening for Metamaterial Absorbers

Simulations



Experiments

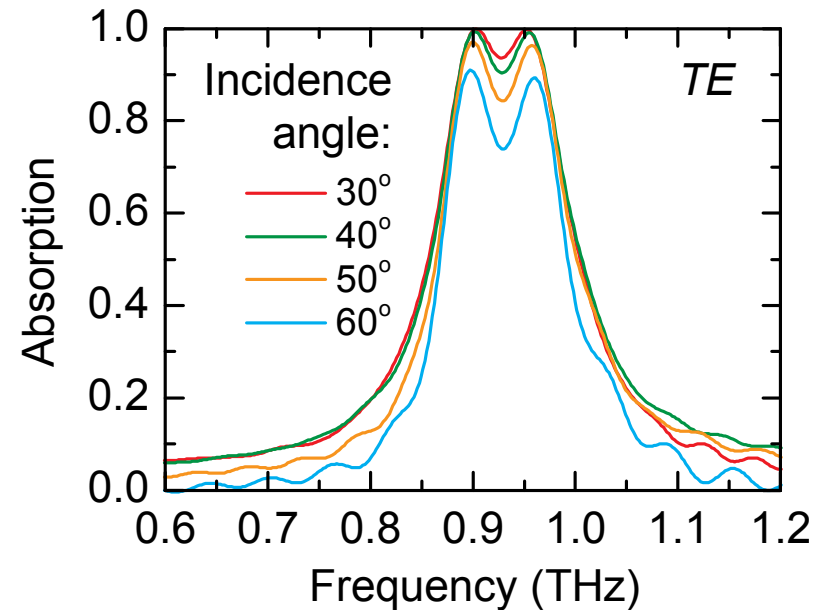
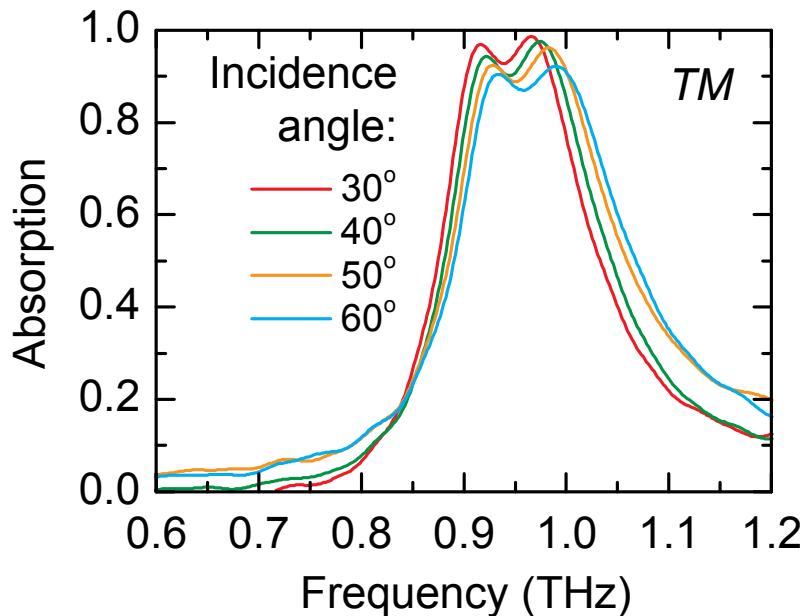
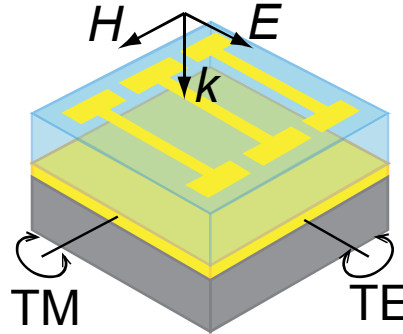


□ Broadening the absorption bandwidth by multiplexing

Huang *et al.*, *Opt. Lett.* **37**, 154 (2012).



High Absorption over a Wide Incident Angle Range



Huang *et al.*, *Opt. Lett.* **37**, 154 (2012).



Boundary Surface Currents

- When EM wave first incident to the resonator array interface, the boundary conditions for magnetic field give the surface current:

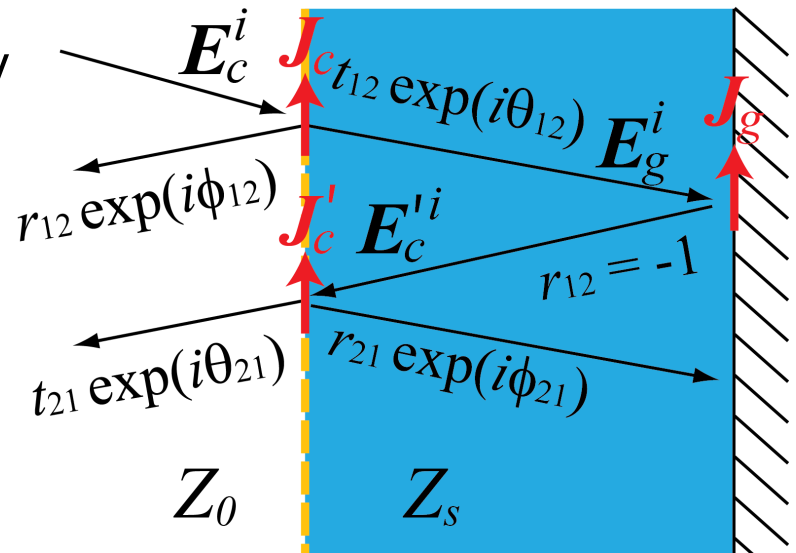
$$J_c = \left[(1 - \tilde{r}_{12}) / Z_0 - \tilde{t}_{12} / Z_s \right] E_c^i$$

- Then it reaches to ground plane and is reflected, the boundary conditions for magnetic field require:

$$J_g = 2E_g^i / Z_s = 2\tilde{t}_{12}e^{i\tilde{\beta}} E_c^i / Z_s$$

- It reaches to resonator interface again:

$$\begin{aligned} J_c' &= \left[(1 - \tilde{r}_{21}) / Z_s - \tilde{t}_{21} / Z_0 \right] E_c'^i \\ &= - \left[(1 - \tilde{r}_{21}) / Z_s - \tilde{t}_{21} / Z_0 \right] \tilde{t}_{12} e^{i2\tilde{\beta}} E_c^i \end{aligned}$$





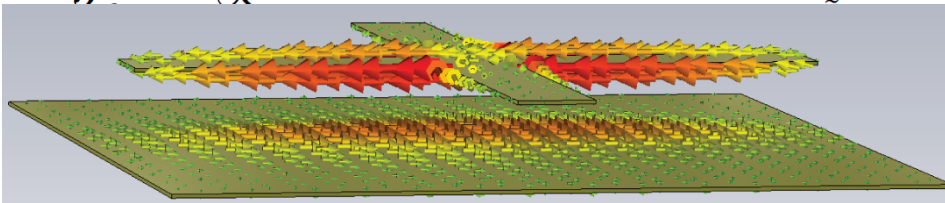
Anti-Parallel Surface Currents by Electrical Excitations

- The total surface currents are the superpositions of each excitation:

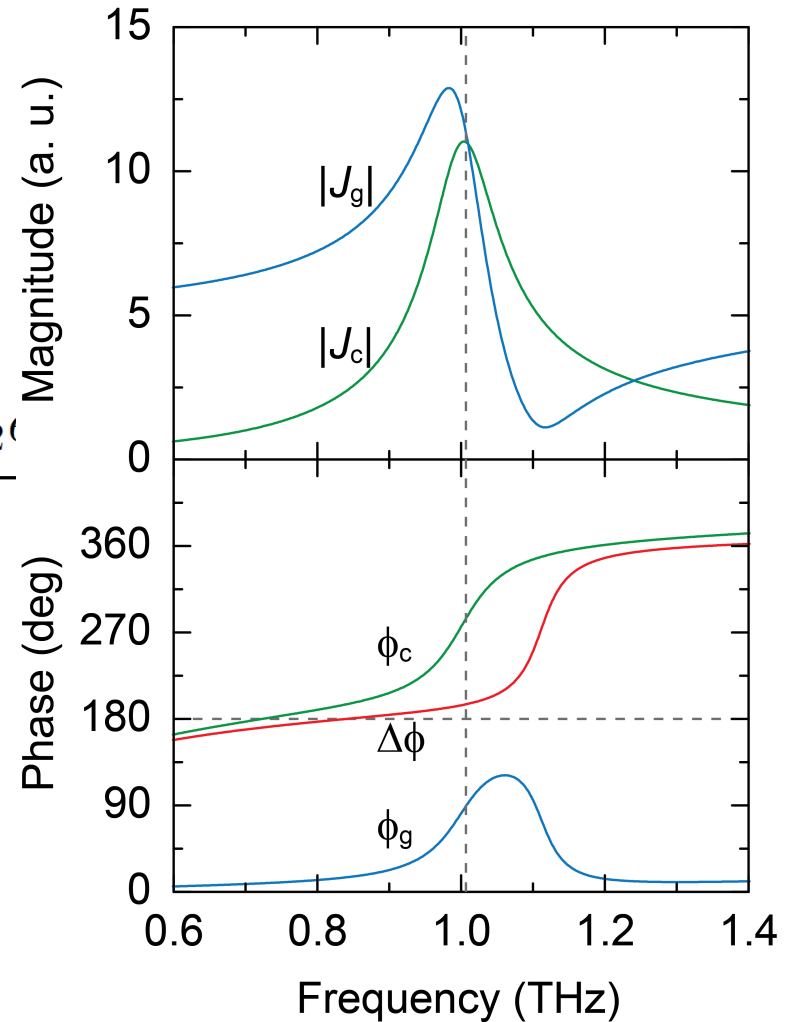
$$J_g^{total} \propto \frac{2\tilde{t}_{12}e^{i\tilde{\beta}}}{1 + \tilde{r}_{21}e^{i2\tilde{\beta}}}/Z_s$$

$$J_c^{total} \propto -\frac{[(1 - \tilde{r}_{21})/Z_s - \tilde{t}_{21}/Z_0]\tilde{t}_{12}e^{i2\tilde{\beta}}}{1 + \tilde{r}_{21}e^{i2\tilde{\beta}}} + [(1 - \tilde{r}_{12})/Z_0 - \tilde{t}_{12}/Z_s]$$

$$J^{total} \propto -\frac{[(1 - \tilde{r}_{21})/Z_s - \tilde{t}_{21}/Z_0]\tilde{t}_{12}e^{i2\tilde{\beta}}}{1 + \tilde{r}_{21}e^{i2\tilde{\beta}}} + [(1 - \tilde{r}_{12})/Z_0 - \tilde{t}_{12}/Z_s]\tilde{t}_{12}e^{i2\tilde{\beta}}$$

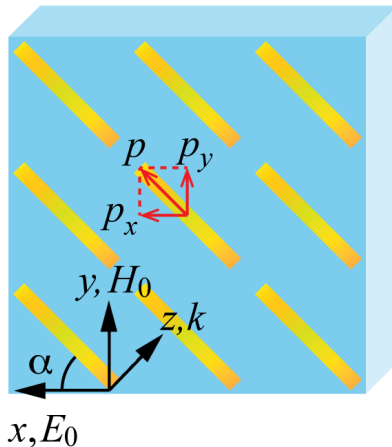


- Anti-parallel surface currents are due to interference and superposition of electrical excitations

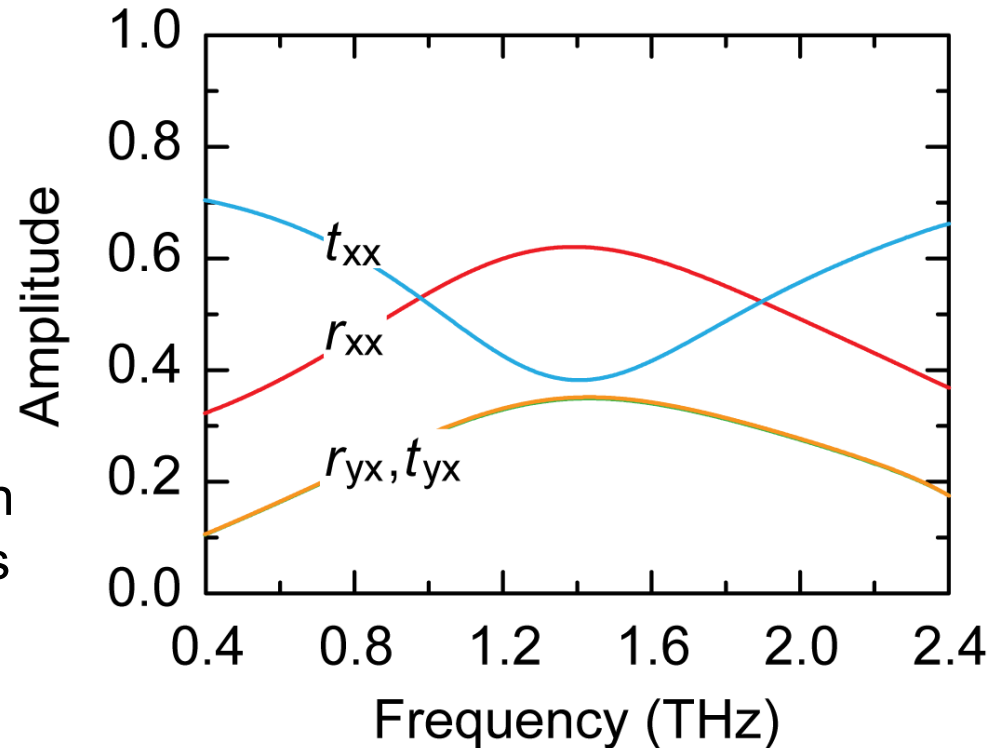




Polarization Conversion in Anisotropic MMs

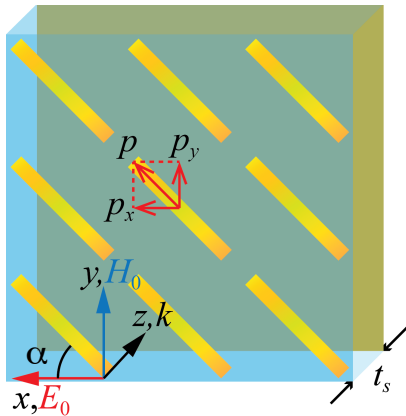


- ❑ Incident field \mathbf{E}_0 along x-direction ($\alpha=45^\circ$): the excited dipole \mathbf{p} has x- and y-components
- ❑ p_x : co-polarized reflection and transmission
- ❑ p_y : cross-polarized reflection and transmission
- ❑ Single-layered metamaterial: polarization conversion is low
- ❑ Output waves are elliptically polarized



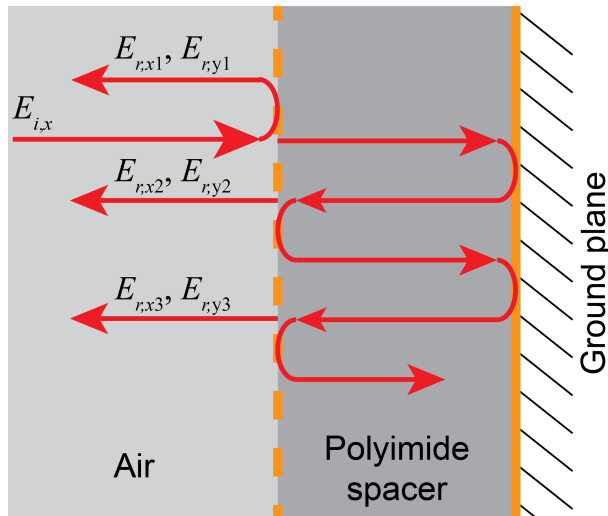


Metamaterial Polarization Converter: Reflection

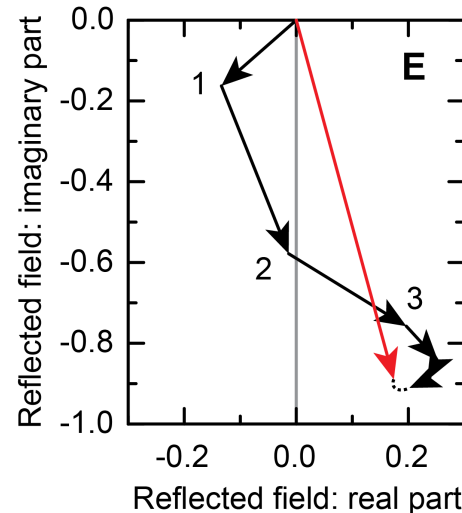


- ❑ Backed with a metal ground plane with appropriate thick dielectric spacer
- ❑ Multiple reflections contain both x and y components
- ❑ The co-polarized multiple reflections interfere destructively, leading to minimal co-polarized reflection
- ❑ The cross-polarized multiple reflections interfere constructively, leading to high cross-polarized reflection

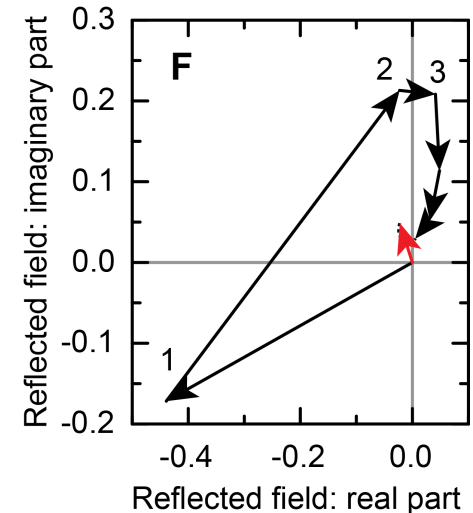
Cut-wire array



cross-polarized

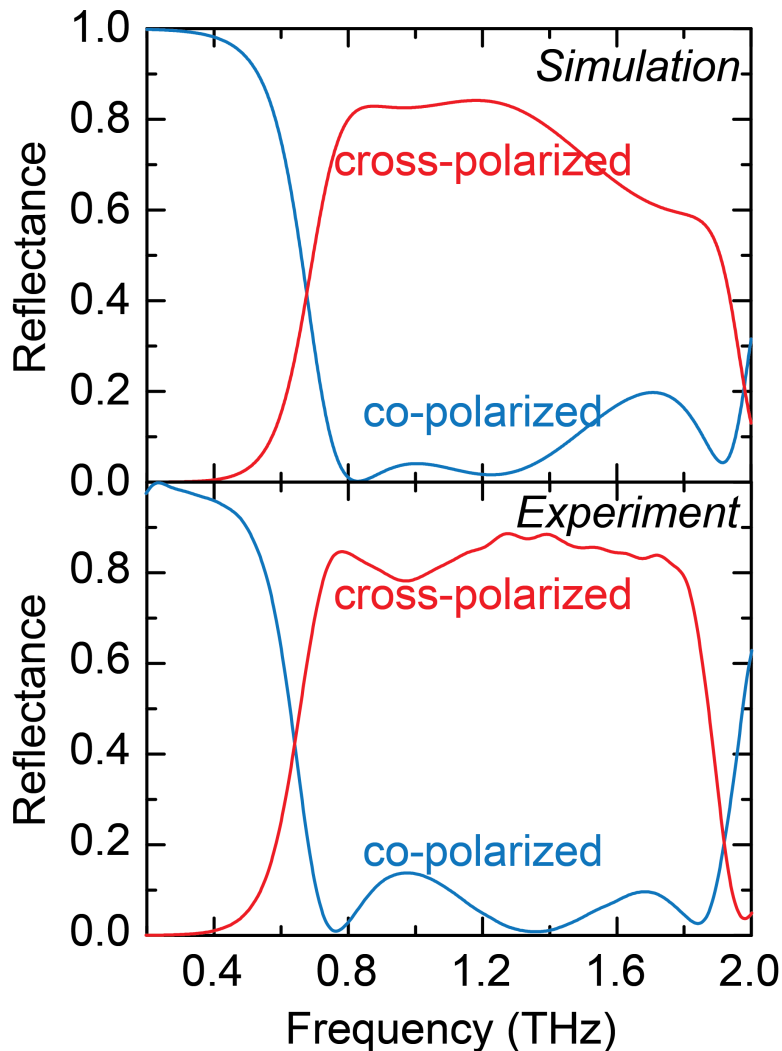


co-polarized





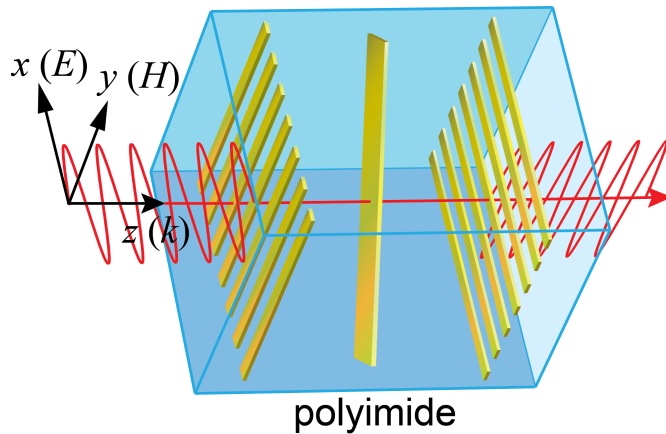
Metamaterial Polarization Converter: Reflection



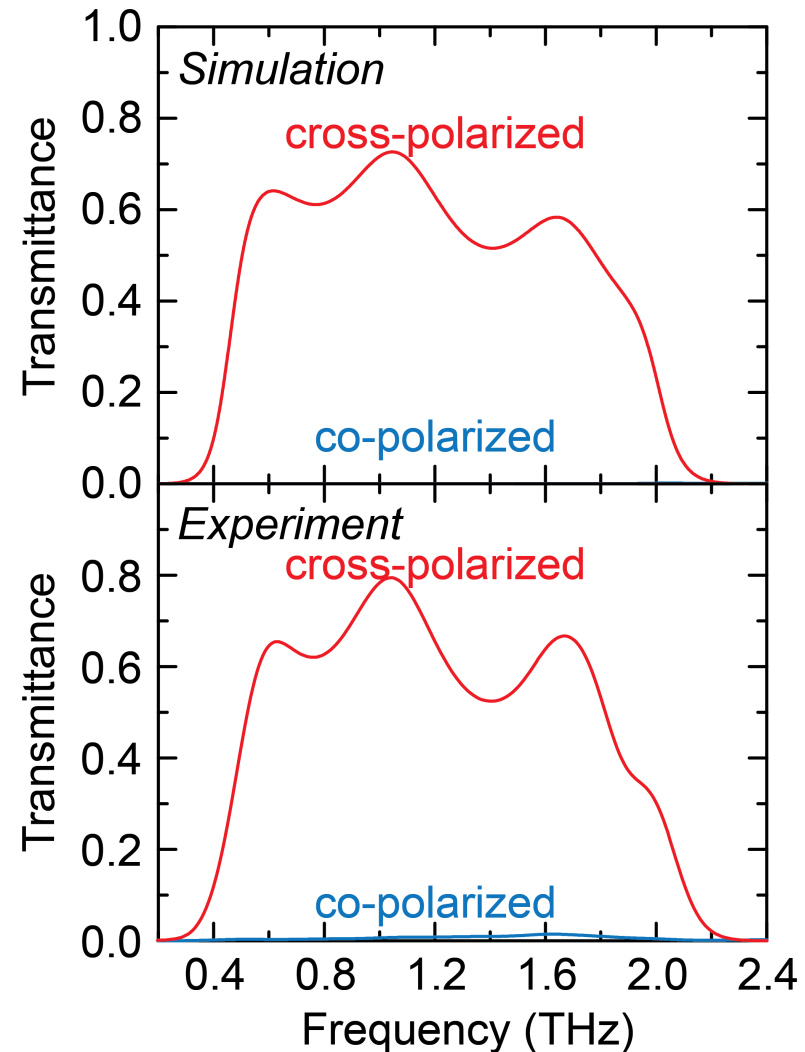
- ❑ Demonstrated in both simulations and experiments
- ❑ Device thickness 33 μm
- ❑ Co-polarized reflection is minimal
- ❑ Cross-polarized reflectance is more than 80%
- ❑ Broadband: destructive interference at multiple frequencies



Polarization Converter: Transmission

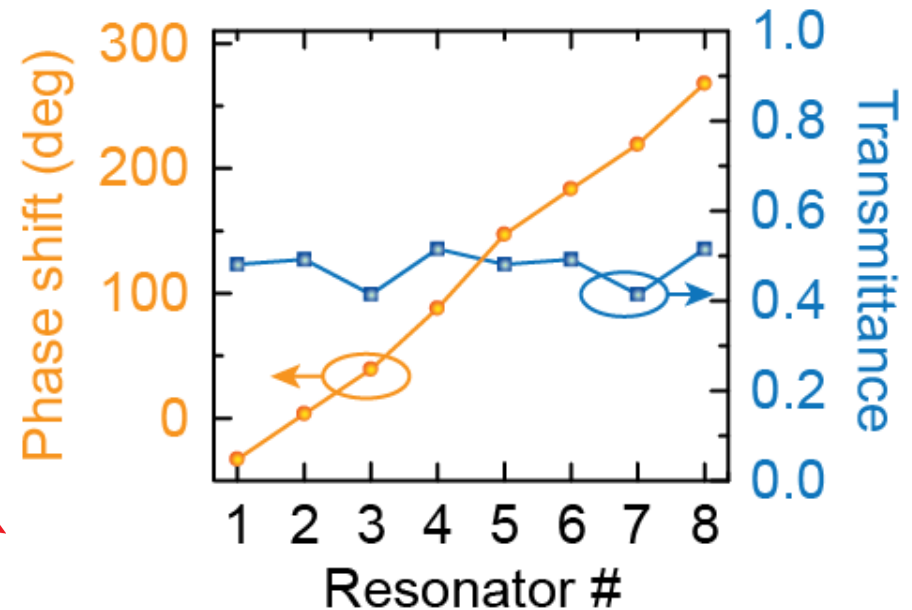
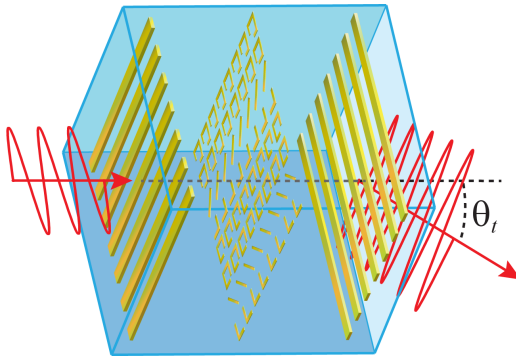
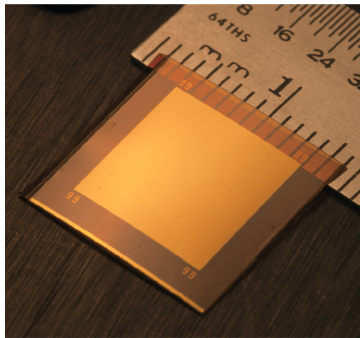


- ❑ The gratings are equivalent to ground plane for electric field polarized along the grating lines.
- ❑ The back grating prevents co-polarized light from transmitting through
- ❑ The front grating prevents the converted cross-polarized light from reflecting back





Anomalous Refraction: Generalized Snell's Law

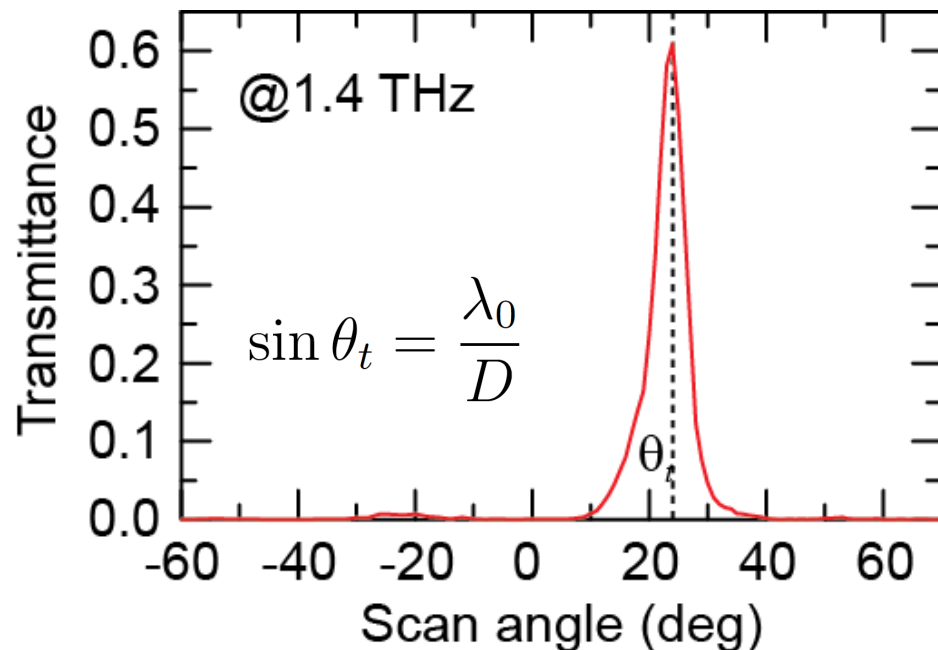
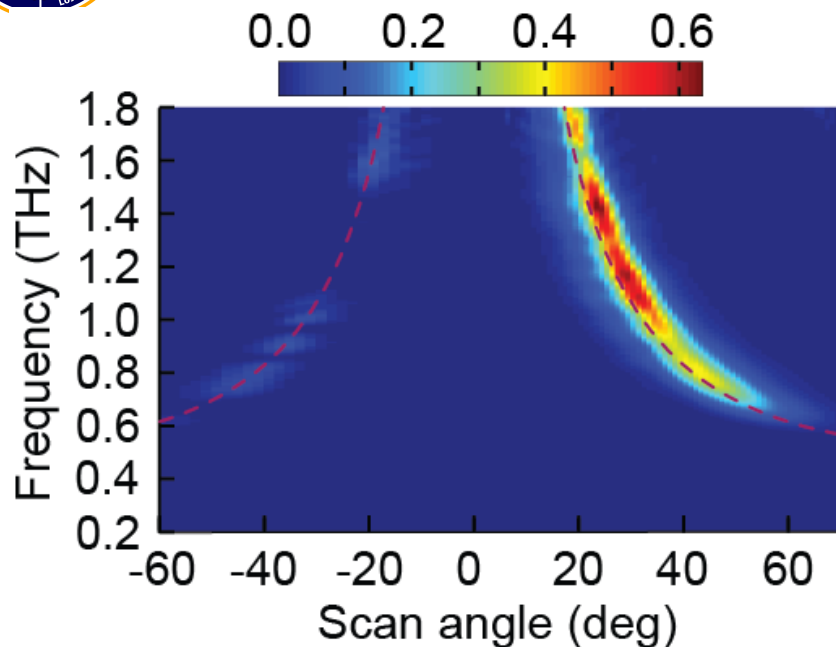


$$\sin \theta_t - \sin \theta_i = \frac{\lambda_0}{2\pi} \frac{d\Phi}{dx}$$

- ❑ Each individual element can be used in polarization converter
- ❑ Conversion efficiency is designed to be largely constant
- ❑ 8 elements form the unit cell, with a linear phase shift spanning a 2π range



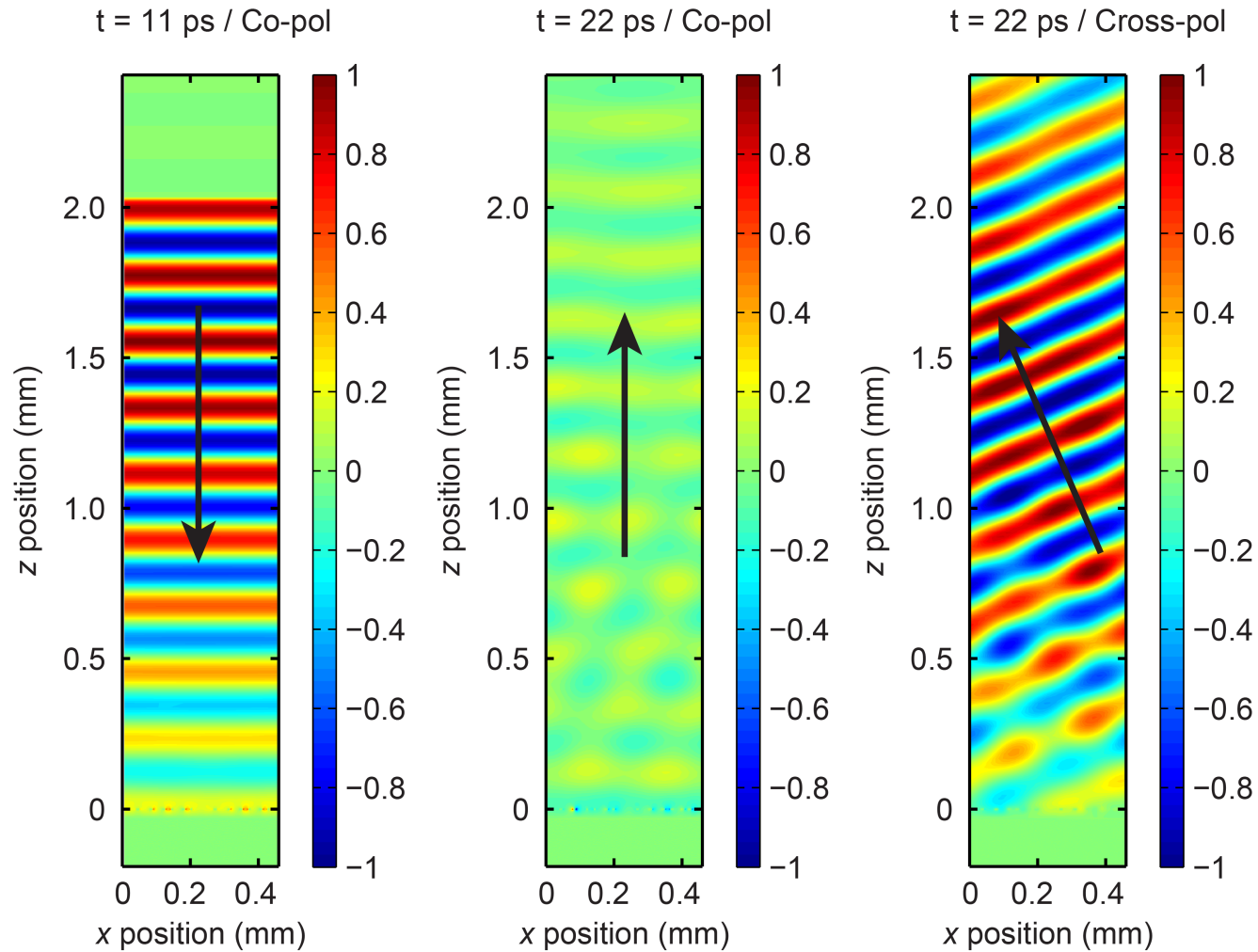
Near-Perfect Anomalous Refraction: Exp.



- ❑ At a specific frequency, the “refraction angle” is determined by periodicity
- ❑ At 1.4 THz, the anomalous refraction carries 60% of the incident power
- ❑ Measure the cross-polarized transmission vs. scanning angle
- ❑ Operate over a broad bandwidth

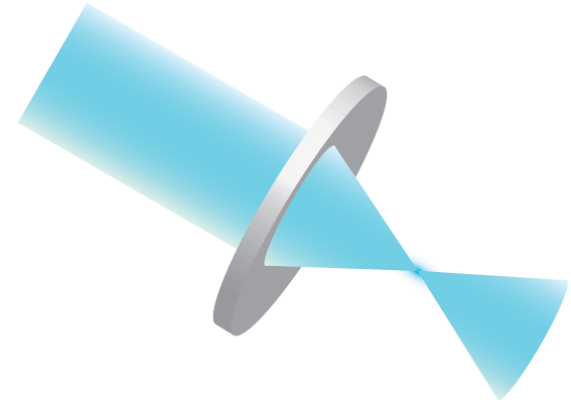
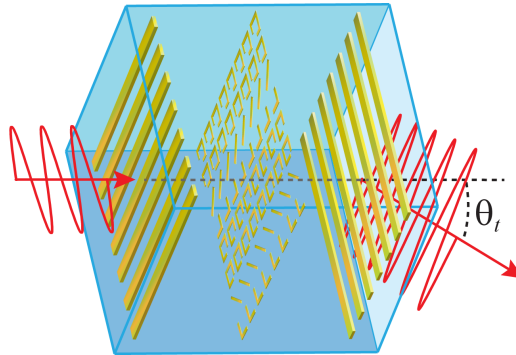
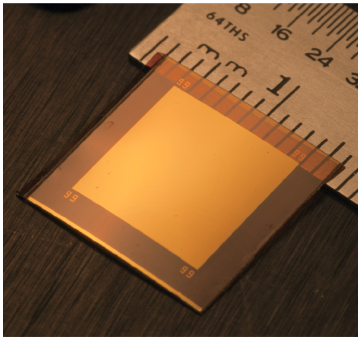


Near-Perfect Anomalous Reflection: Simulation

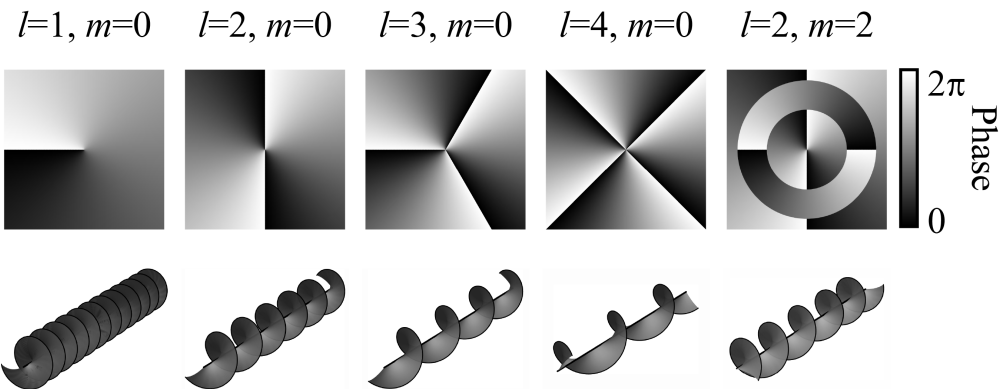




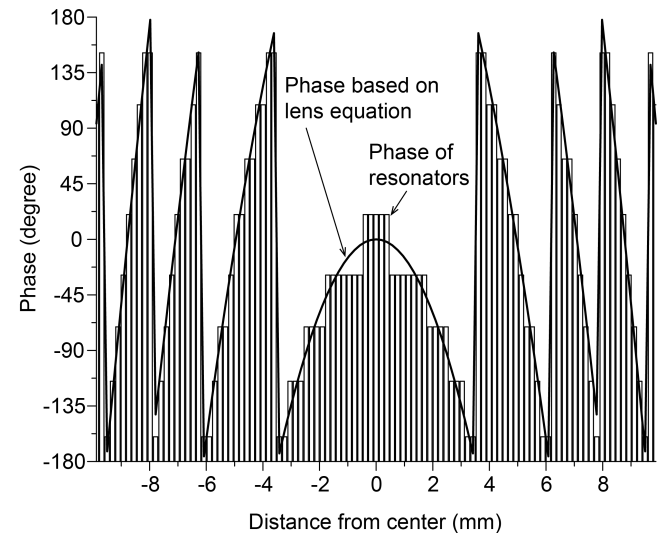
Flat Optics



□ Flat prism for beam steering



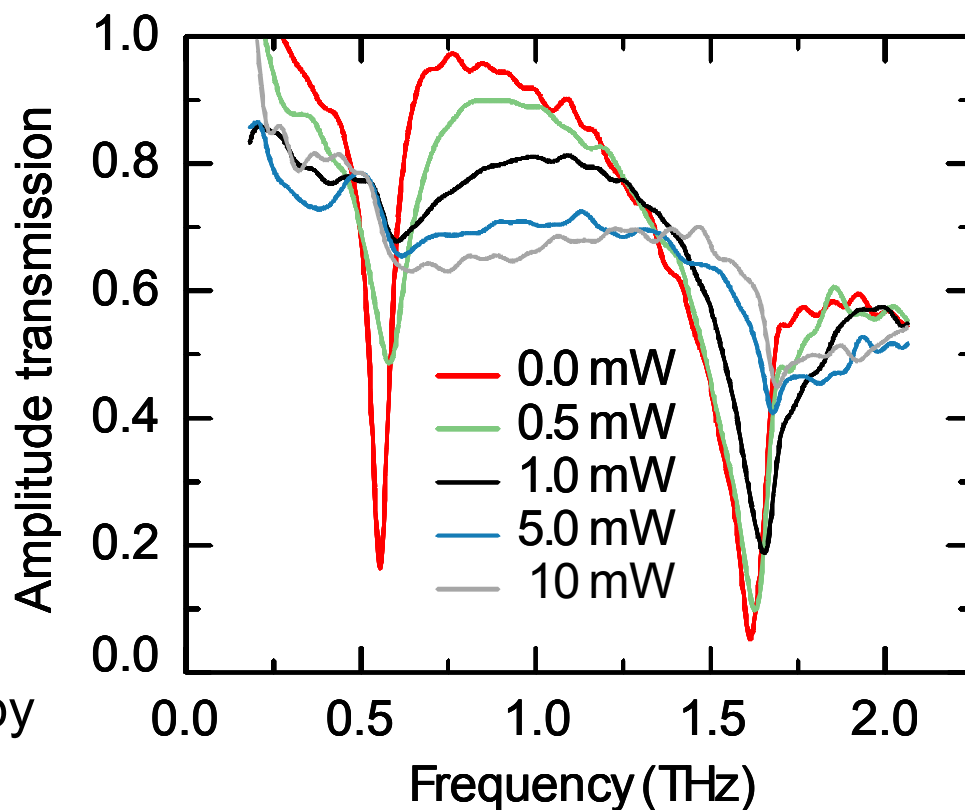
□ Wave front shaping



□ Flat lens for beam focusing



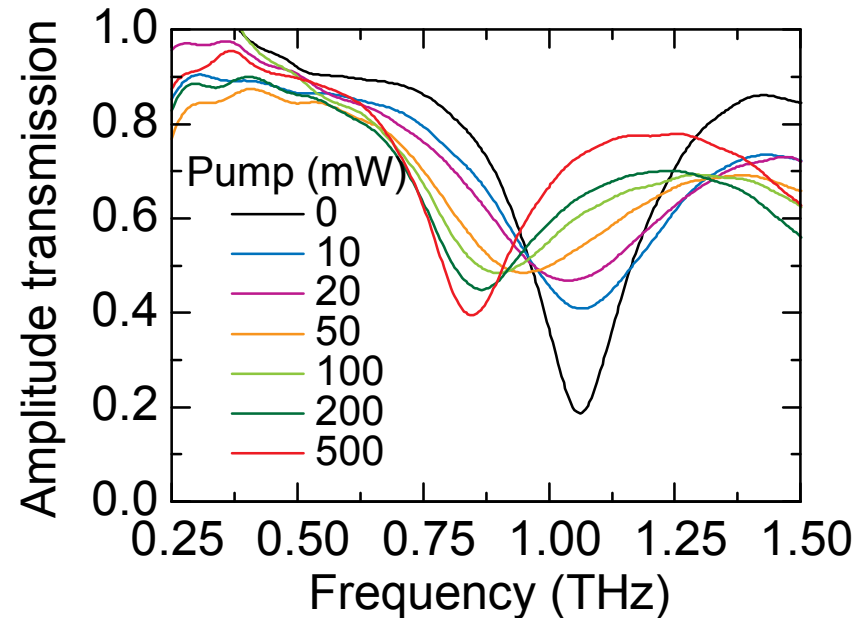
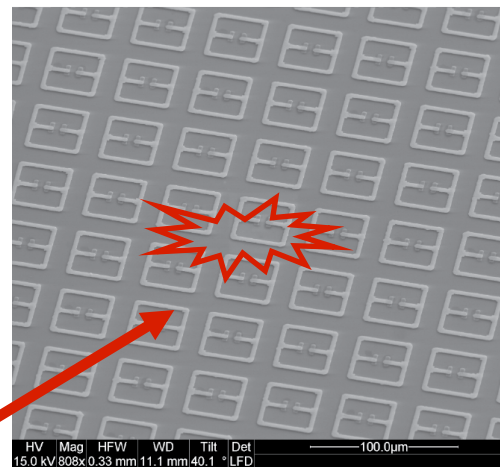
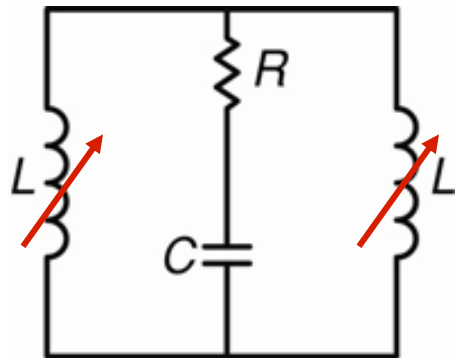
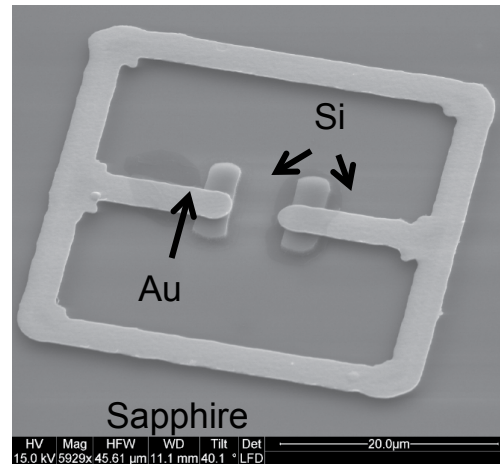
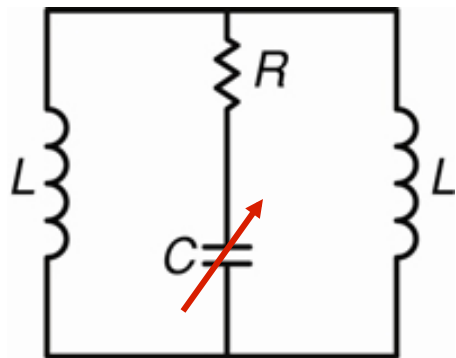
Optically Switchable Terahertz Metamaterials



- Switching speed is only limited by carrier lifetime (\sim ns for GaAs)
- \sim ps by reducing the carrier lifetime (GaAs:ErAs nano superlattice)



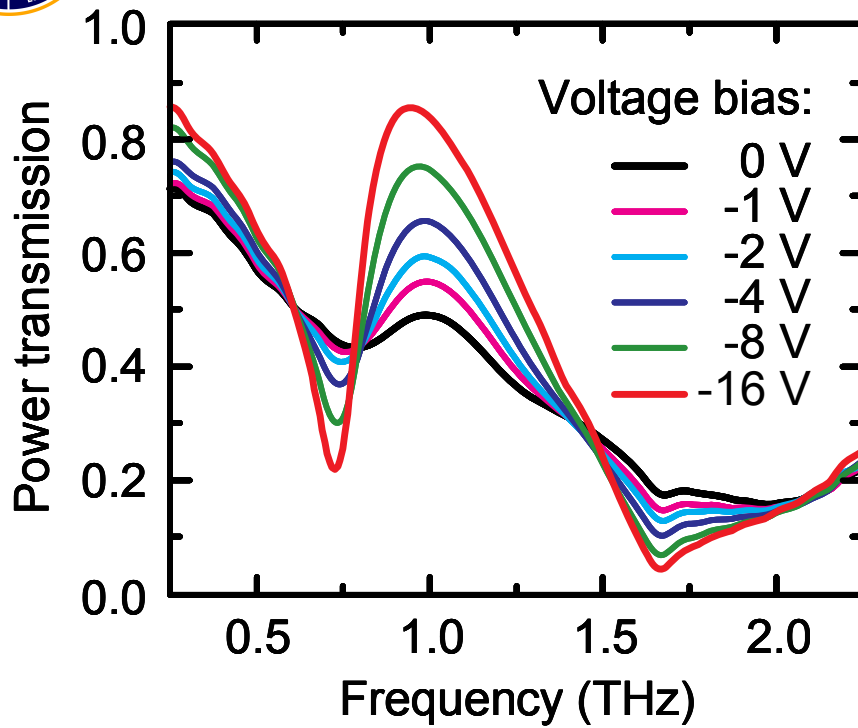
Optically Frequency Tunable Terahertz Metamaterials



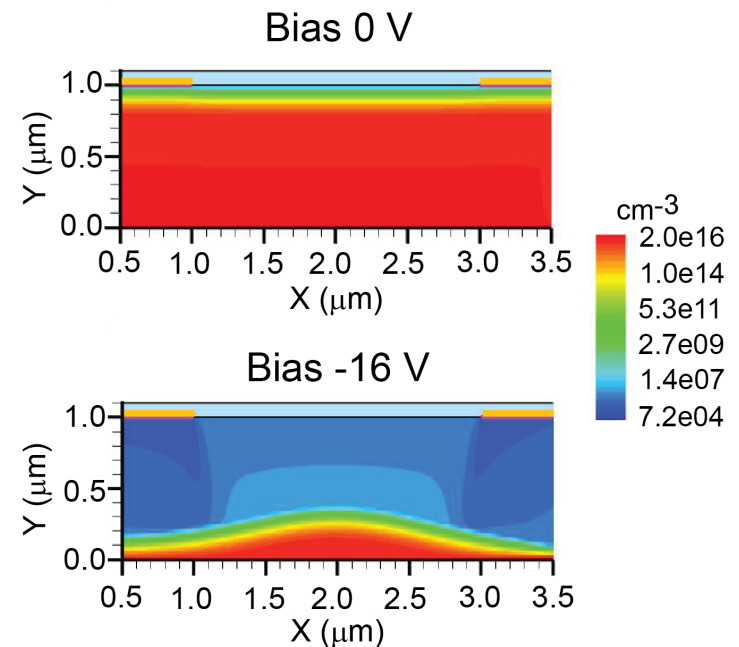
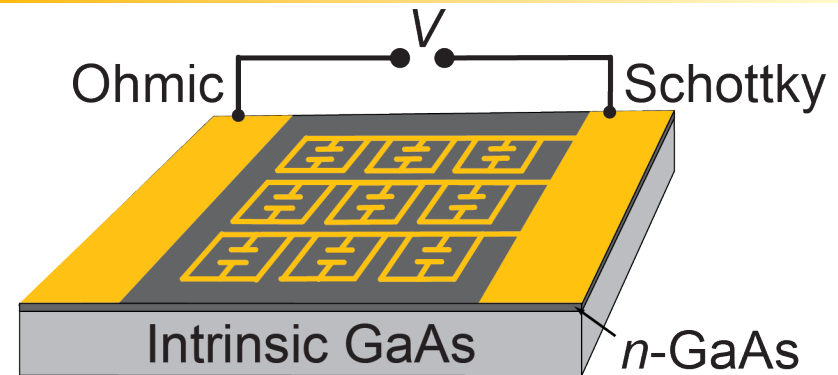
- ~20% frequency tuning range
- Could be red or blue shifting



Electrically Switchable Terahertz Metamaterials



- Amplitude modulation depth 50%
- Phase modulation of $\Delta\phi = \pi/6$
- Operate at room temperature



Chen *et al.*, *Nature* **444**, 597 (2006).

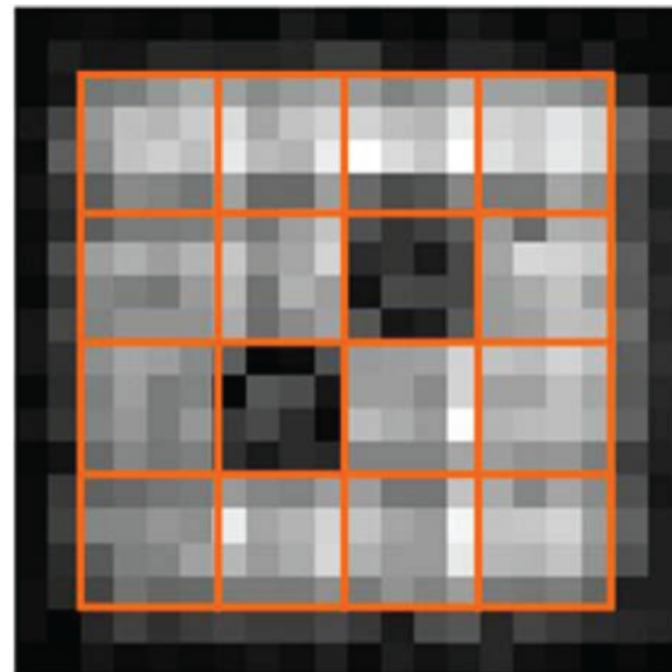
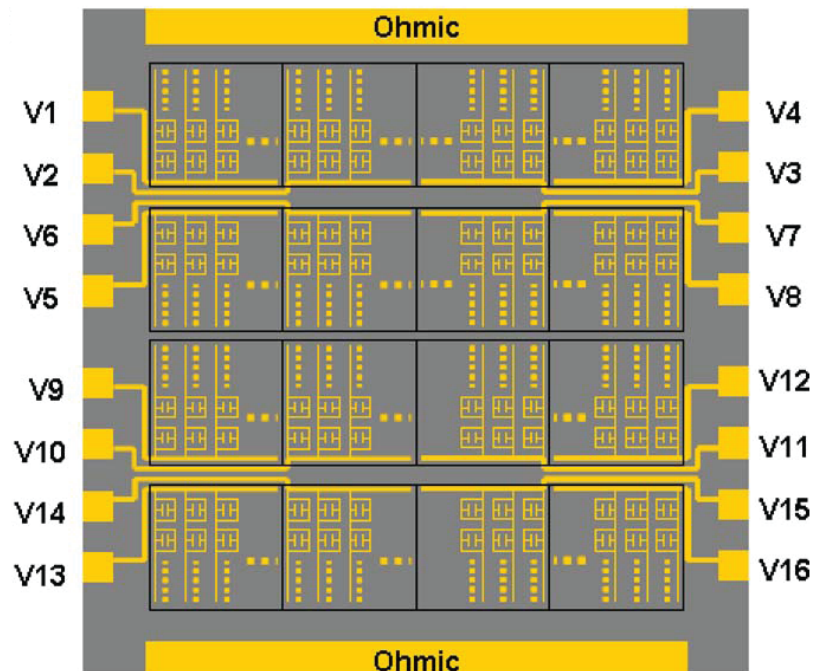
Chen *et al.*, *Nat. Photon.* **3**, 148 (2009).

Chen *et al.*, *Opt. Express* **16**, 7641 (2008).

Chen *et al.*, *APL* **93**, 091117 (2008).



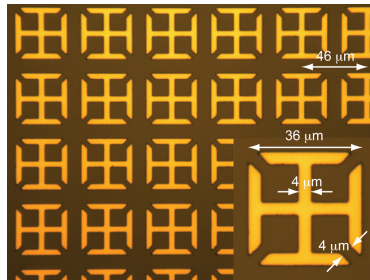
Terahertz Spatial Light Modulator



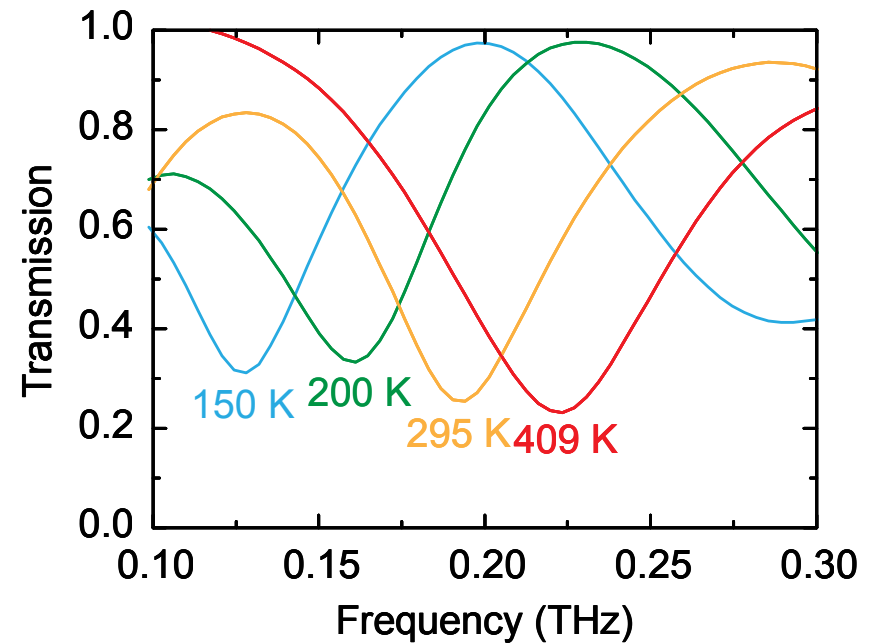
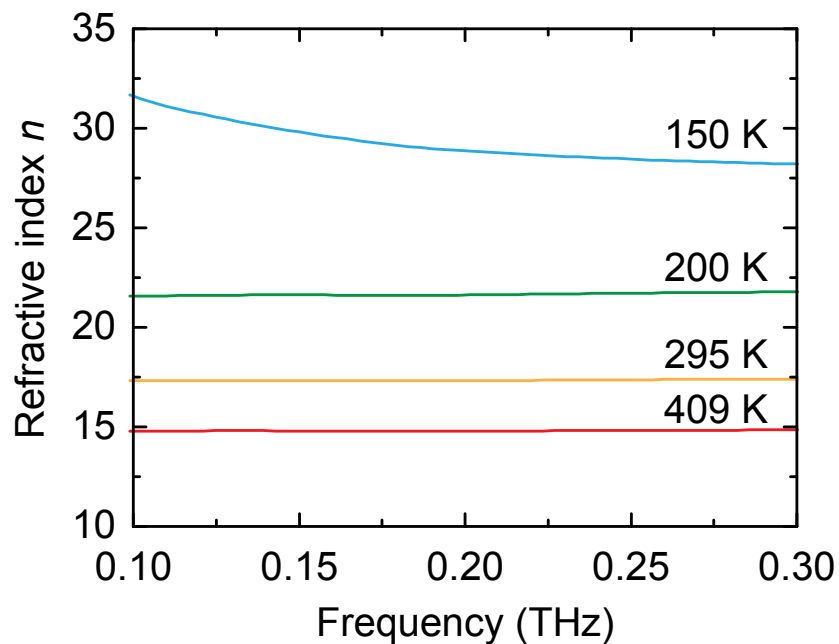
- Each pixel consisting of hundreds of SRRs
- Resonance can be independently switched at each pixel
- For high-speed terahertz imaging



Thermally Tunable Metamaterials Using Ferroelectric Substrate (Strontium Titanate)

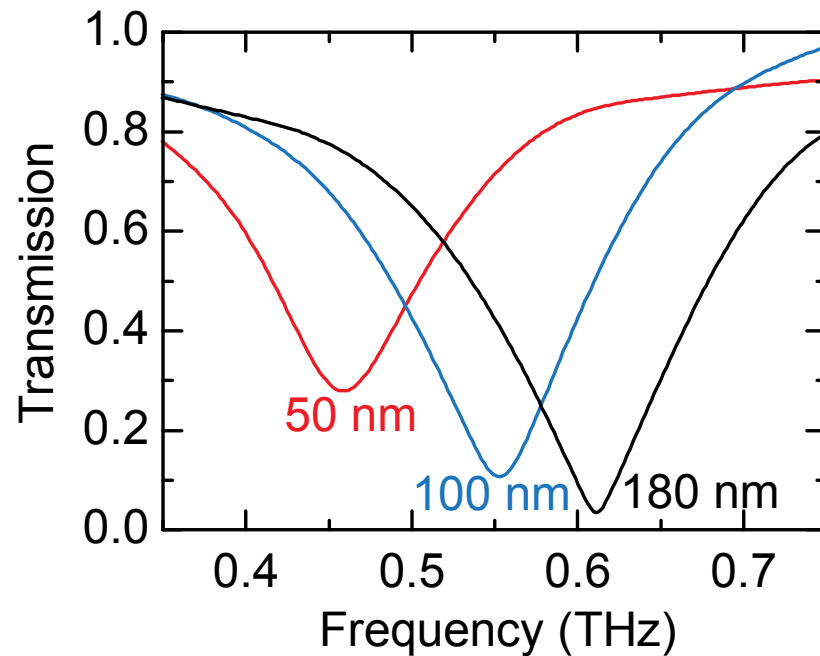
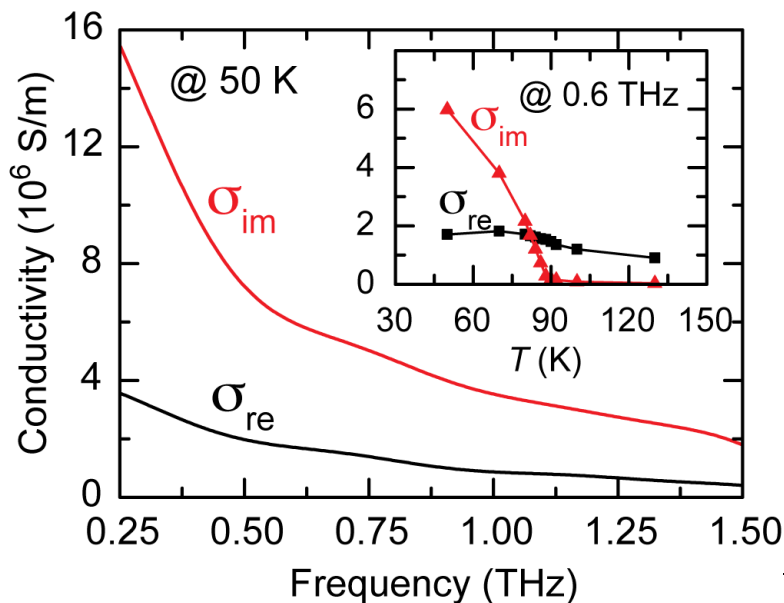
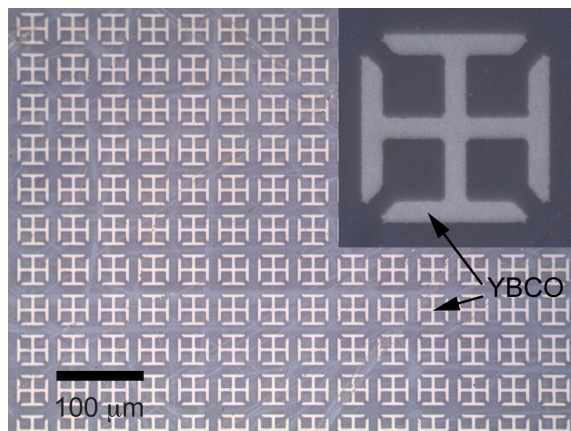


- Substrate refractive index (dielectric constant) decreases with decreasing temperature
- Resonance frequency red-shifts with decreasing temperature



High-Temperature Superconducting (HTS) Metamaterials

Epitaxial YBCO film on LAO by Pulsed Laser Deposition with $T_c \sim 90$ K and thickness 180 nm

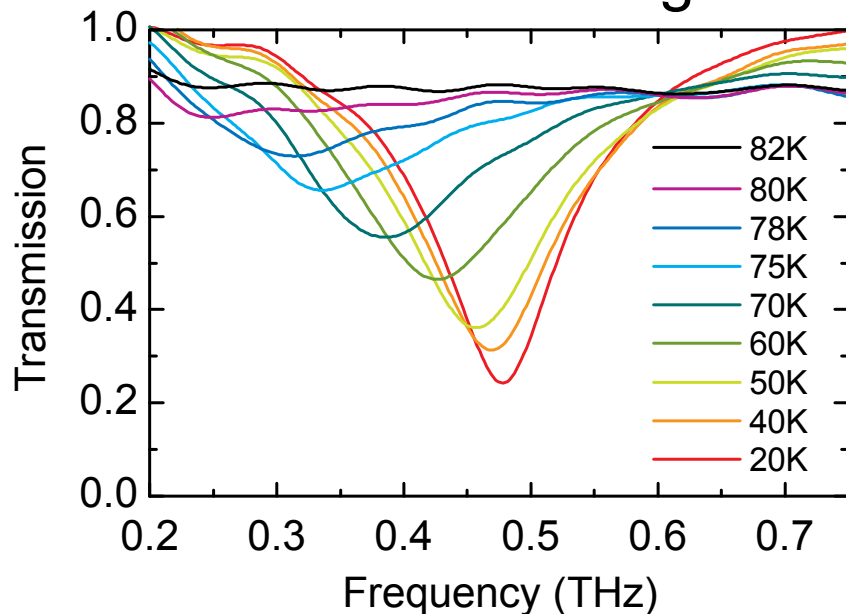


- Strong resonant response at low temperatures
- Resonance frequency strongly depend on the nano-scale thickness
- Need to take into account the kinetic inductance in YBCO metamaterials

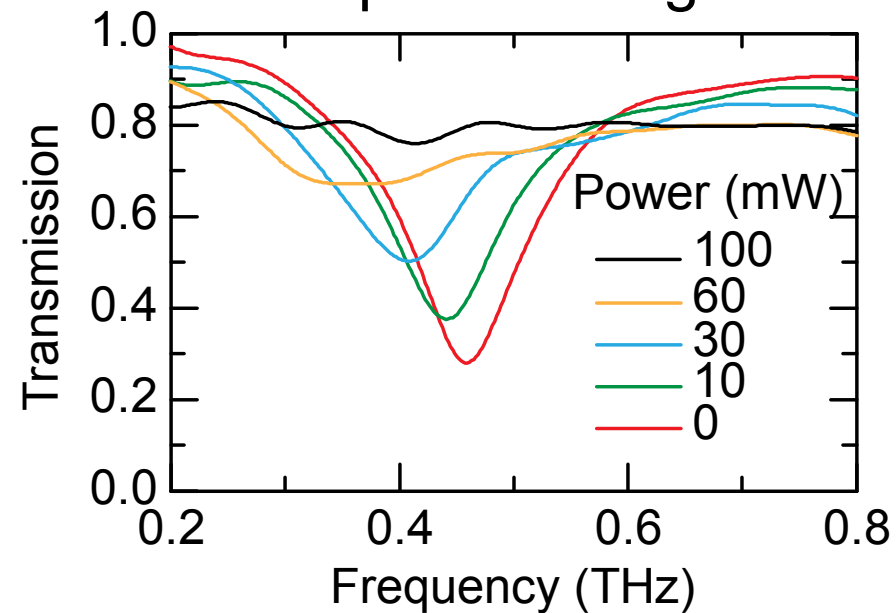


Thermal & Optical Resonance Tuning in HTS Metamaterials

Thermal tuning



Optical tuning



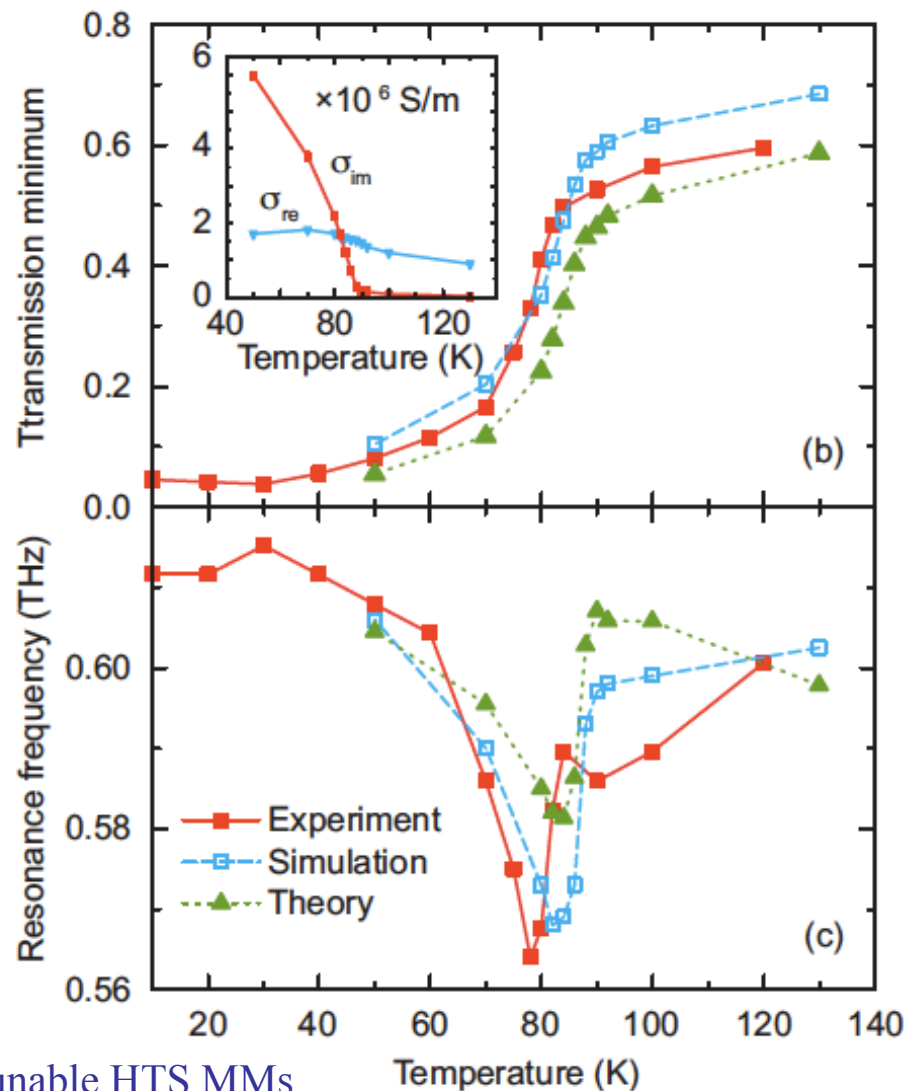
- 50 nm thick YBCO metamaterial
- Resonance strength and frequency are both tuned by temperature
- Imaginary conductivity plays a key role
- The resonance tuning is more significant in thinner YBCO metamaterials



Comparison: Experiment, Simulation, and Calculation

180 nm thick YBCO MM

- Measured, simulated and calculated values of transmission and resonance frequency in agreement.
- Use experimentally measured complex conductivity, plotted at 0.6 THz.
- Finite-element numerical simulations using Comsol Multiphysics
- Imaginary conductivity plays a key role through the kinetic inductance



(Calculations for optically tunable HTS MMs are also in agreement with experiment.)



Metamaterials will play an increasingly important role in THz S&T

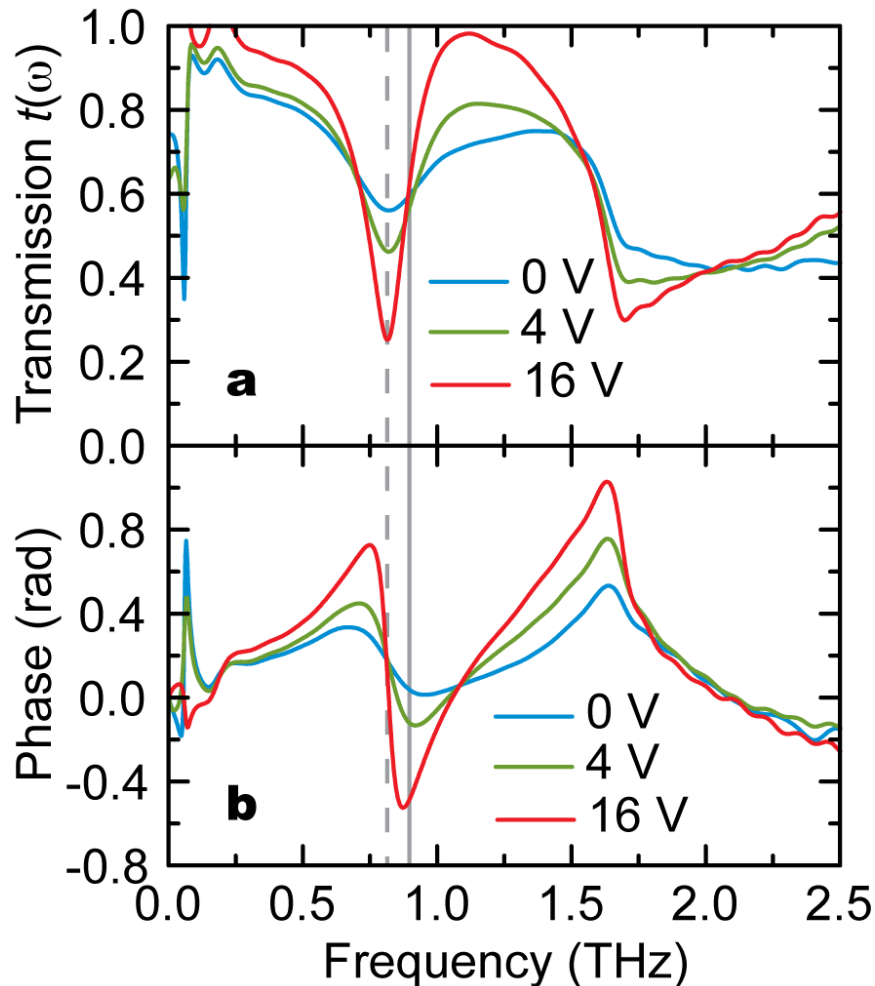
- ❑ Few-layered ultrathin planar metamaterials can accomplish many optical functionalities of bulk materials
 - Ultrathin metamaterial perfect absorbers
 - Ultrathin metamaterial antireflection coatings
 - Thin film like metamaterial linear polarization converters
 - Near perfect anomalous reflection/refraction: generalized Snell's law
- ❑ Electrically switchable THz metamaterials
 - High modulation (intensity and phase) depth
 - Integration into spatial modulator
 - Broadband modulation
- ❑ Optically switchable, frequency tunable THz metamaterials
 - Low optical fluence, high efficiency
 - Ultrafast switching
 - 20% frequency tunability
 - Temperature & optical tunability with complex oxide metamaterials



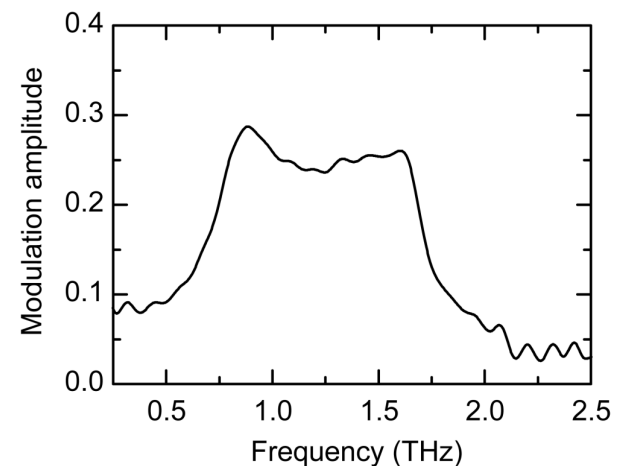
Back-up slides



Amplitude and Phase Modulation



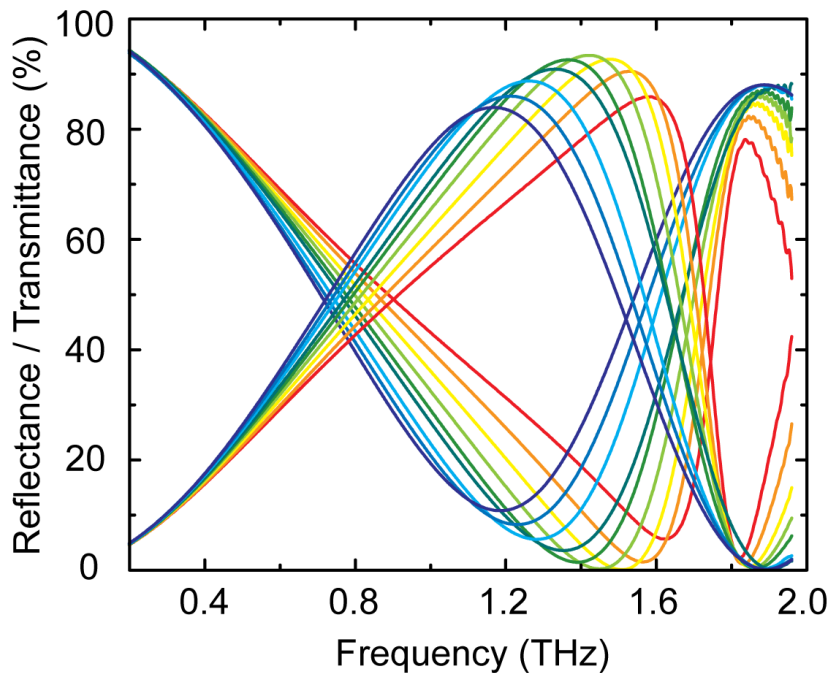
- Power modulation depth:
 $M = (T_{0V} - T_{16V}) / T_{0V} = 80\%$, or
 amplitude modulation depth 55%
- Phase modulation $\Delta\phi = \pi/6$
- Amplitude and phase modulations are correlated
- Both amplitude and phase modulations contribute to the modulation signal resulting in broadband modulation



$$|\Delta \tilde{t}(\omega)| = |t_{V1}(\omega)e^{i\phi_{V1}(\omega)} - t_{V2}(\omega)e^{i\phi_{V2}(\omega)}|$$



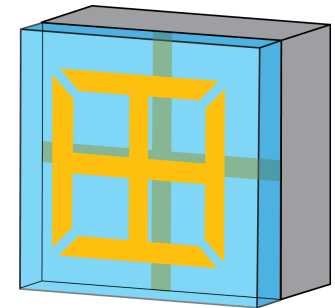
Numerical Simulations: Spacer Thickness



Simulation:

Substrate: $\epsilon_{\text{GaAs}} = 12.7$

MM spacer: $\epsilon_{\text{spacer}} = 1.5$



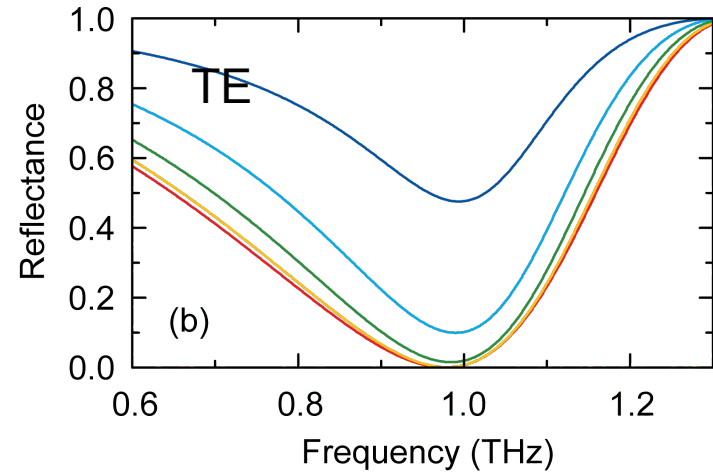
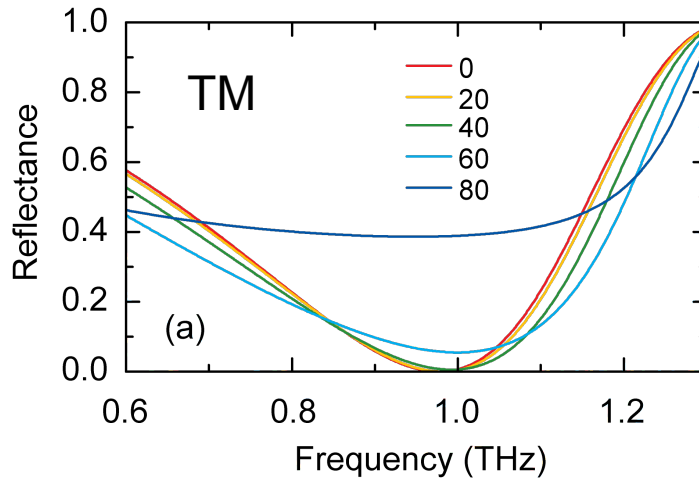
From red to blue:

Increasing the spacer thickness from 4 μm to 20 μm

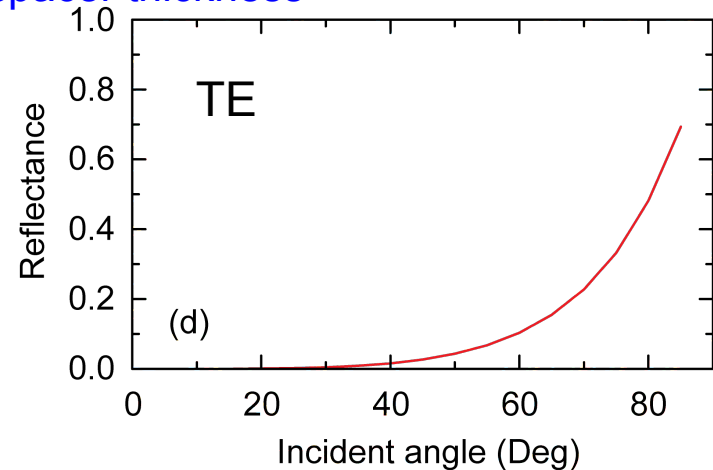
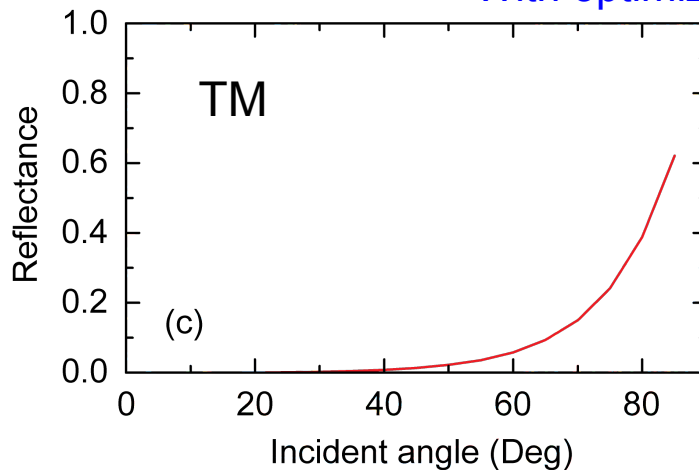
- With any dielectric constant of the spacer material, there is always a thickness achieving excellent antireflection, even the spacer dielectric constant is larger than the substrate
- The losses in metal and the spacer material mainly affect the transmittance, but has little effect on the reflectance



Numerical Simulations: Angular Dependence



With optimized spacer thickness





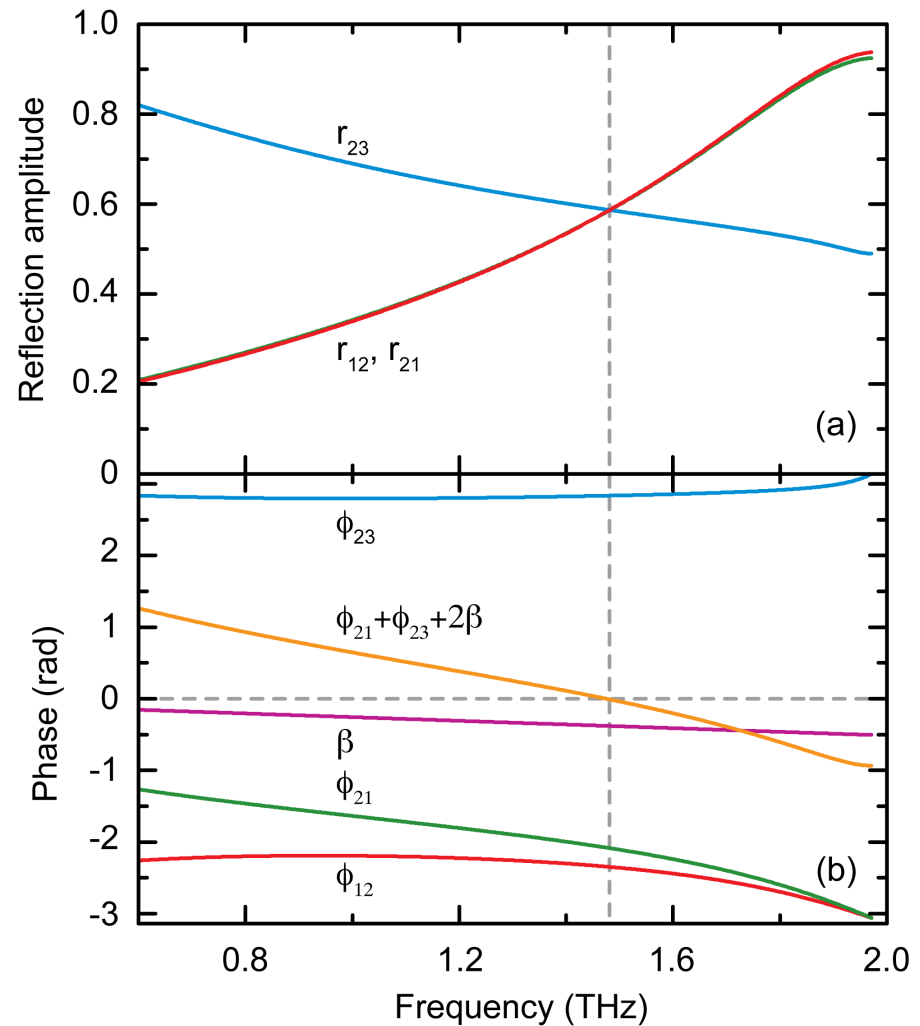
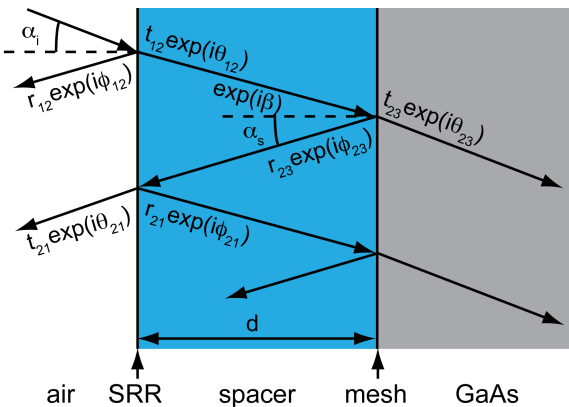
Antireflection Mechanism: Modeling Results

- Antireflection requirements:

$$r_{12} = r_{21} = r_{23},$$

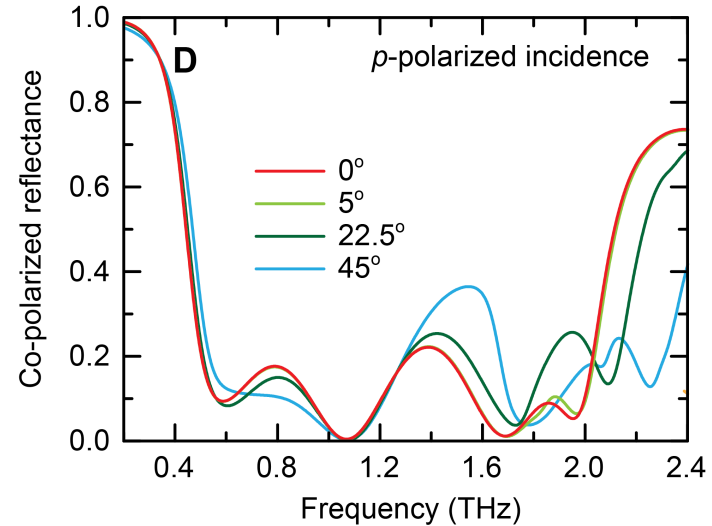
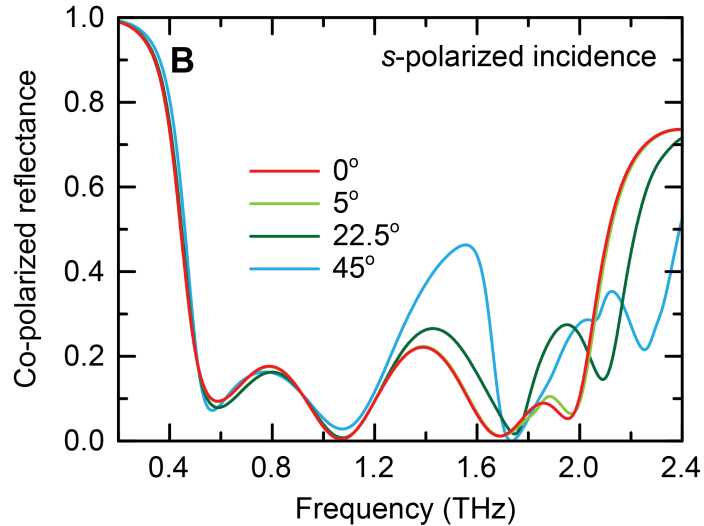
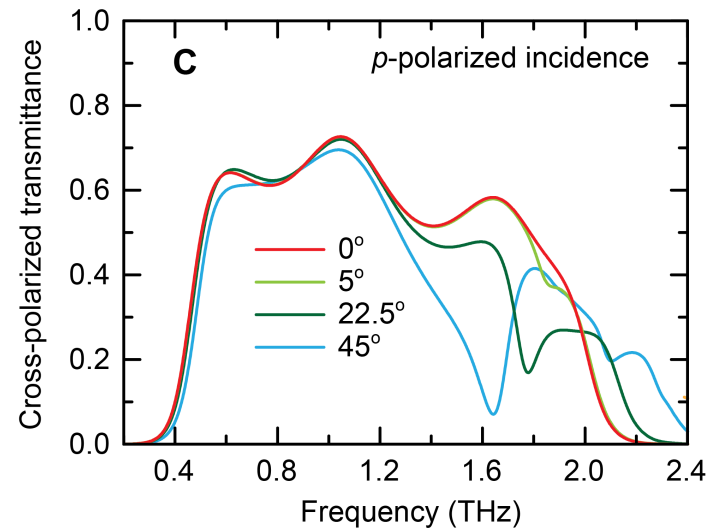
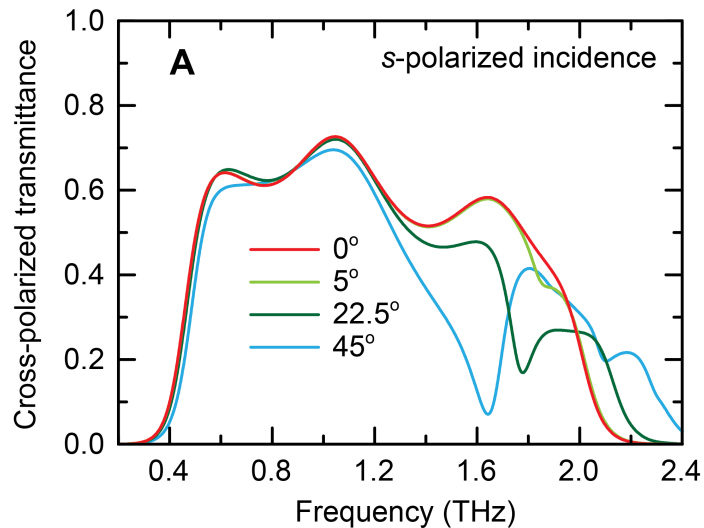
$$\phi_{21} + \phi_{23} + 2\beta = 2m\pi$$

- Varying β (spacer thickness) reproduces the thickness dependent reflection and transmission





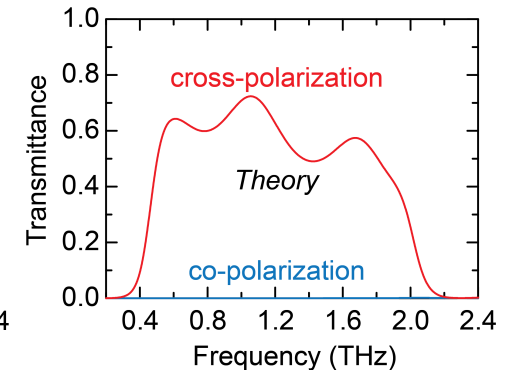
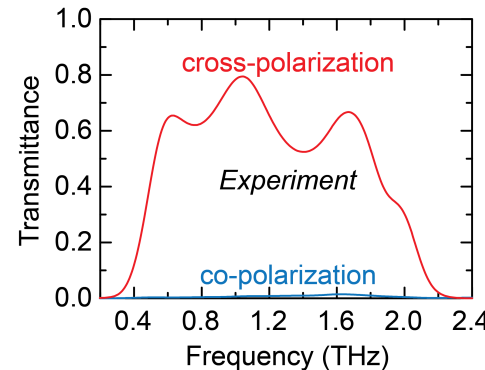
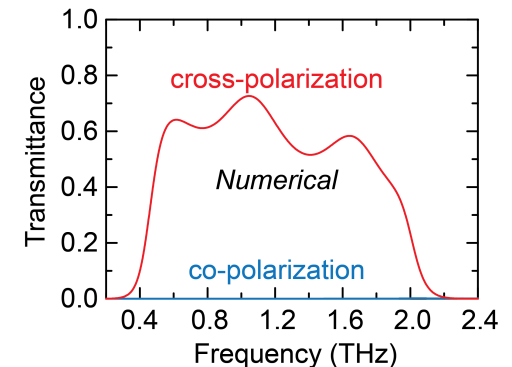
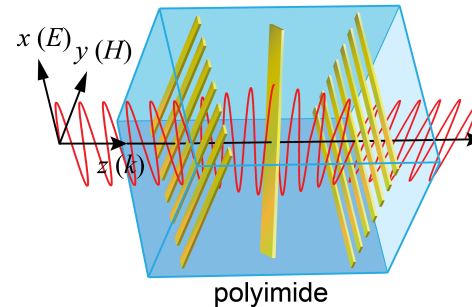
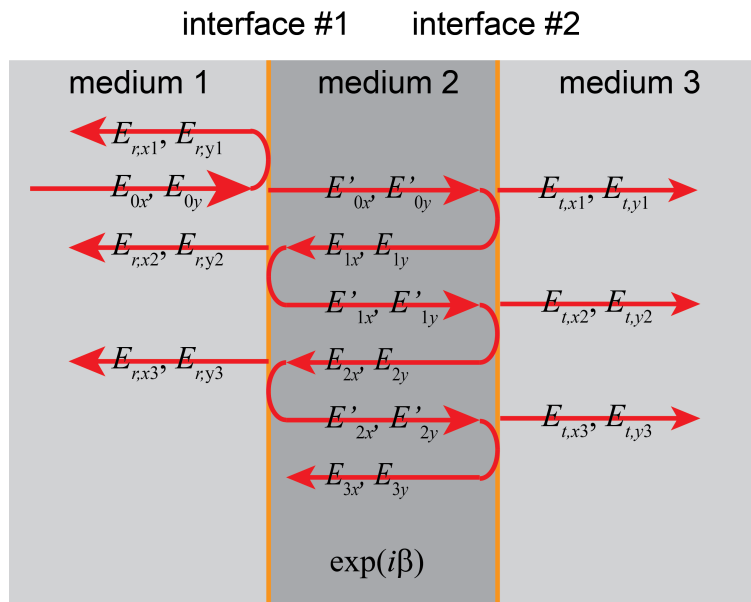
Polarization and Incident Angle Dependence





Modeling Metamaterial Polarization Conversion

- ❑ Reflection and transmission coefficients from numerical simulations
- ❑ Superposition for the overall reflection and transmission





Antireflection Coatings

➤ Quarter-wave antireflection

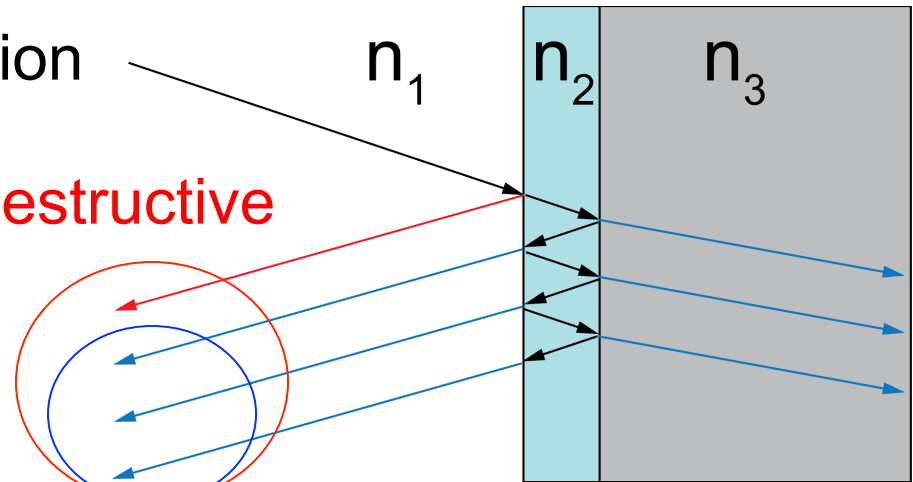
$$n_2 = \sqrt{n_1 n_3}$$

$$d = \lambda/4$$

- ✓ Index matching
- ✓ Thick coating

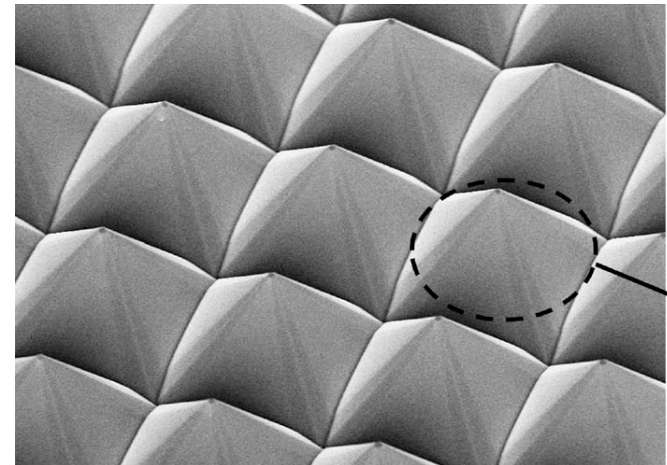
Destructive

Constructive



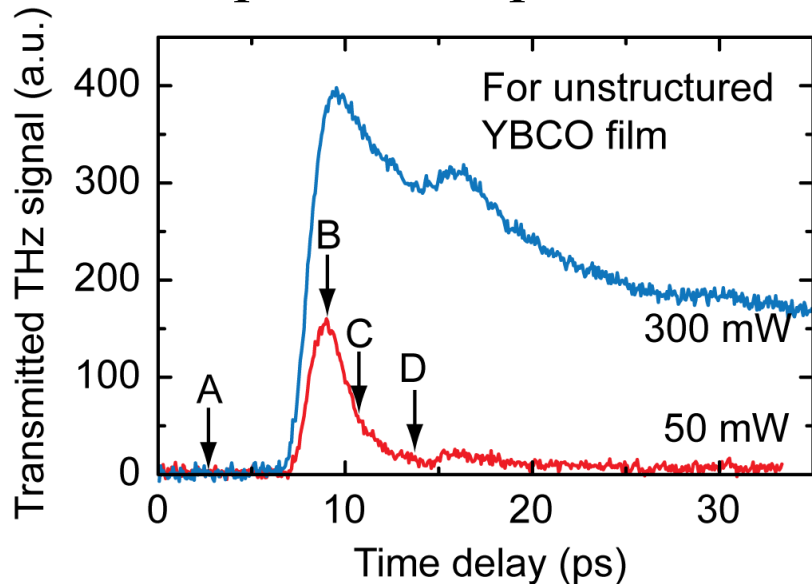
➤ Antireflection using surface relief structures

- ✓ Specific for certain materials
- ✓ Surface is no longer smooth for further integration

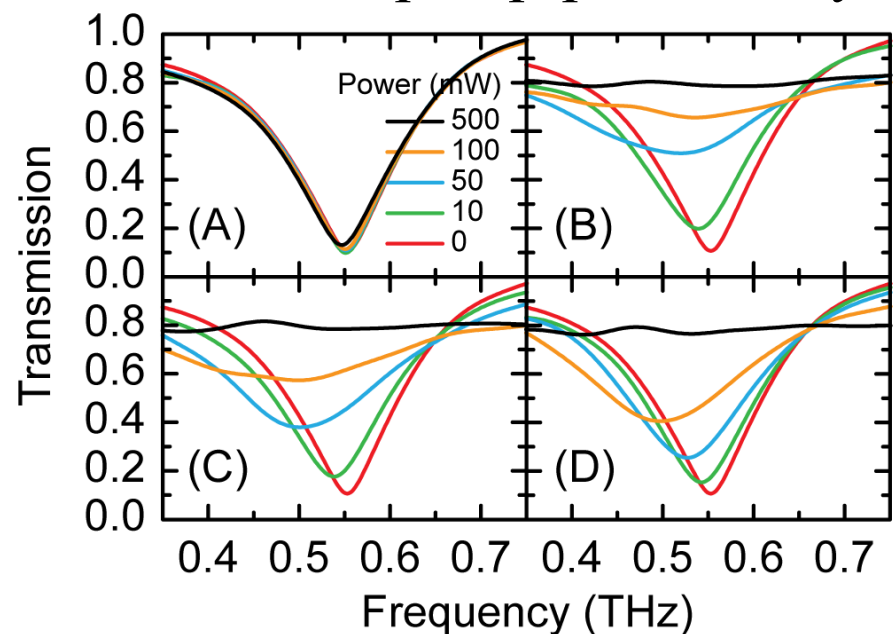




Optical Pump THz Probe



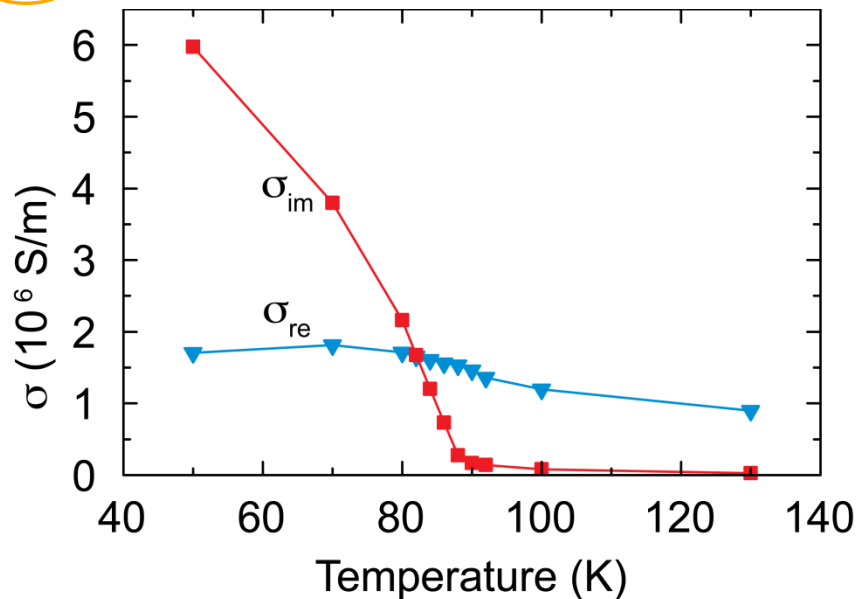
At various pump-probe delays



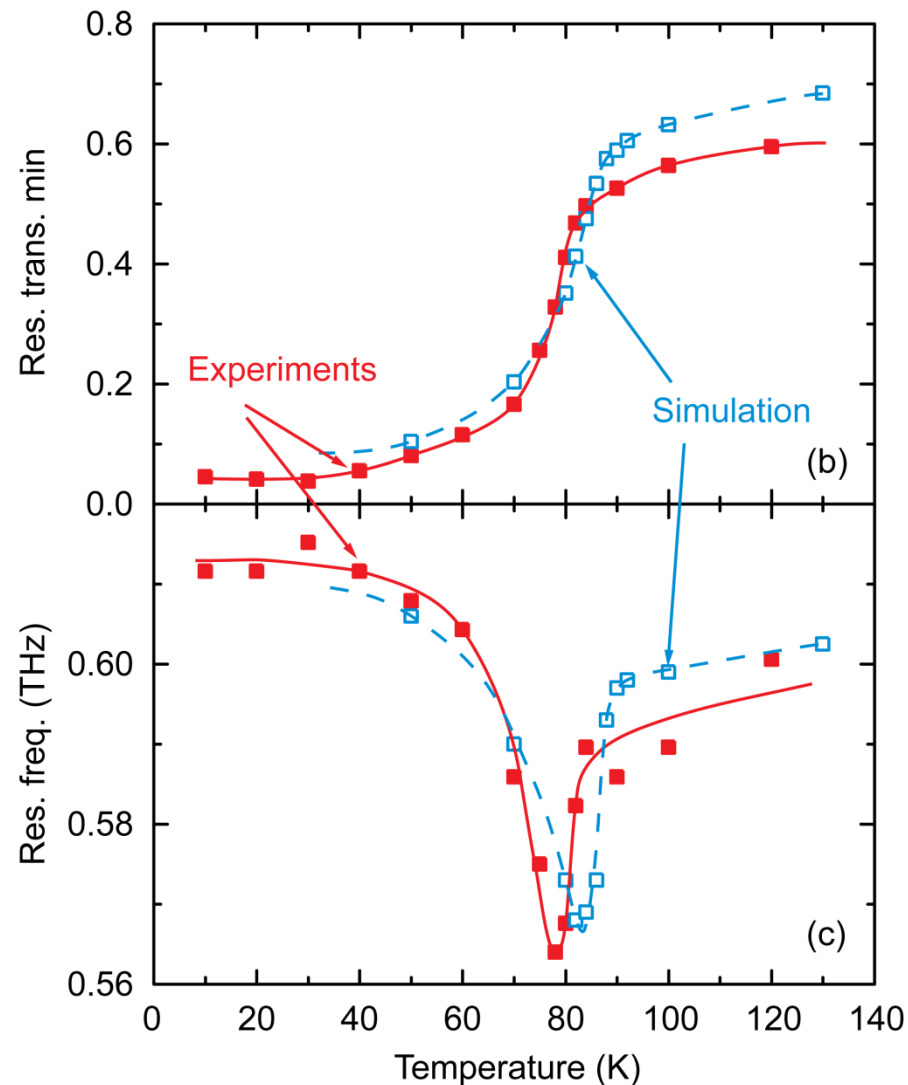
- Relaxation (recombination) time is a few ps
- Increasing the pump power results in a long relaxation tail due to thermal effects



Thermally Tunable Resonance: Experiment and Simulation

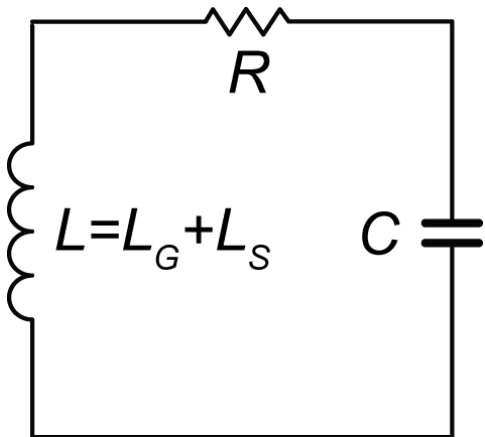
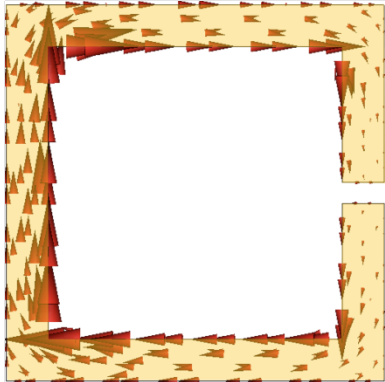


- Experimentally measured the complex conductivity, plotted at 0.6 THz
- Finite-element numerical simulations using Comsol Multiphysics





Resonance in Split Ring Resonators



- The resonance frequency is given by:

$$\omega^2 = \frac{1}{LC} - \frac{R^2}{4L^2}$$

- The capacitance C : determined by the geometry and dimensions of the split gap, and assume no change
- The inductance L :
 - ✓ Loop L_G
 - ✓ Additional (kinetic) inductance L_S from SRR superconducting strips
- L_S becomes important when the film thickness is comparable or smaller than the skin depth



SRR Resistance and Inductance

➤ Surface impedance:

$$Z_s = R_s - iX_s = Z_0 \frac{n_3 + i\tilde{n}_2 \cot \tilde{\beta}}{\tilde{n}_2^2 - n_3^2}$$
$$\tilde{n}_2 = \sqrt{i\sigma/\epsilon_0\omega} \quad \tilde{\beta} = \tilde{n}_2 d\omega/c_0$$

➤ When $|\tilde{n}_2| \gg n_3$, it can be simplified as:

$$Z_s = i \frac{Z_0}{\tilde{n}_2} \cot \tilde{\beta}$$

➤ By considering the non-uniform currents, the surface resistance of the *SRR array* is given by:

$$R = \frac{A}{w} R_s$$

- A is the loop circumference
- w is the SRR linewidth

➤ Additional kinetic inductance:

$$L_s = \frac{1}{\omega} \frac{A}{w} X_s$$



Thickness Dependent Surface Impedance

When reducing the HTS film thickness:

- Increasing surface resistance R_s : high damping for thinner YBCO metamaterials
- Increasing kinetic inductance L_s : lower resonance frequency for thinner YBCO metamaterials
- The turning point in L_s results in the resonance frequency back shift.

